BOX 2 Folder 29

Heat to Electric Power Transducer, 1958



July 73 58 analysis of . Thermo-electron Engine " Ket .: Measured Thermal Efficiencies of a Diodo Configuration of a Sermo Elictror Engen G.N. Hatsopoulos + J. Kaye Z. appl. Phys. 29, 1124 (1988) $F_{\rm Lh}$ $\phi' = \phi_1 + V_5$ at the critical condition of onsitof space charge at collect with V3 = VT, the current flow is given day 51.1 ou $I_m = 7.729 \times 10^{-12} \frac{T^3}{\omega^2}$ $\sigma_{T_{m}} = 9.664 \times 10^{-6} \frac{V_{r}^{3}}{\omega_{2}} \int \frac{51.7}{\omega_{1}}$

7/23/08 2 There are the same as. 58.1 or 78.2 conerted forw 2 The condition That this current during is flowing is $i = AT^{2}e^{-\frac{\phi}{V_{T_{i}}}} = AT^{2}e^{-(\frac{\phi}{V_{T_{i}}}+1)}$ = A e'T, 2 = \$, i=ie of the applied potential is quate dan the critical one then $i'=i_0e'e'V_T$ Di=i-i'=ie'(1-e-V) for very small values of AV we have $\Delta \dot{c} = \dot{c}_0 e^{-1} \Delta v$ and $\frac{\Delta V}{\Delta i} = \frac{V_T}{i e^{-i}}$ this is the internal resistance of the

generator and should 7/23/18 3 be matched by the external logd to get max power out $R_{e} = \frac{\alpha V_{T}}{\alpha 9.664 \times 10^{-6} V_{T}^{-3} r_{z}} = \frac{1}{\alpha} \frac{\alpha \omega^{2}}{9.664 \times 10^{-6} V_{T}^{-2}}$

For the example of H+K T= 1550°K |T²=2.4×10⁶ |T⁴=5,77×10' V_T=.1336 $(\omega^2 = (2.54 \times 10^{-5})^2 = 6.45 \times 10^{-10}$ V/2= ,3655 V7 2 = ,04883

 $R_e = \frac{6.45 \times 10^{-10}}{a \cdot 9.664 \times 10^{-6} \times .3655} = \frac{1.88 \times 10^{-4}}{a}$

area used by HK was. $\left(\frac{2.54\times10^{-2}}{8\times2}\right)^{2}TT = 7.91\times10^{-6} = a$

 $R_{e} = \frac{1.88 \times 10^{-4}}{.791 \times 10^{-5}} = 23.8^{\circ}$

7/23/58 Current would be I = 7.91×10 × 9.66 × 10 × 4.88×102 6.45×10-10 = 5,8 × 10-3 V = 5,8×10-3×23.8 = ,138 = V_ Since AV = internal resistance = V+ abi and P= I2R in load if work function were equal. $P = \frac{a^{2}(i_{0}e^{-1})^{2}V_{T}}{a(i_{0}e^{-1})} = a^{2}i_{0}e^{-1}V_{T}$ $= \alpha \frac{9.664 \times 10^{-6} V_{T}^{3/2} (V_{T} + \phi_{1} + V_{T} - \phi_{2})}{\omega^{2}}$

Returning to the Fig 1

assume that i = 1.20×10 × 2.4×10 e =

= 7,3×102

2,864 6.079 6,38 12.459 ,1336 . <u>9.595</u> = $\phi' = 2,95$ p, = 2,82

Take \$2 = 1.4

V = 1.55 $R = \frac{1.55}{7.3 \times 10^{2} \times 7.91 \times 10^{-6}} = 2.7 \times 10^{2}$

= 270 W

7/23/58

270" × 5.8× 10" = 1.56 To check, $P_0 = 9 \times 10^{-3} \text{ watte.}$

7/23/58 Power lost legradiation at surface: Nr = 5,65 × 10 T a x(Er) = 3,26 × 10° a *(Er) take Er = ,2 $a = 7.9 \times 10^{-6}$ Pr = .515 watt $y = \frac{.9 \times 10^{-2}}{.515} = 1.75 \times 10^{-2}$ actorge in voltege appen by 2 V- would increase the current ley v 2,5 so that taking a $V_0 = 1.56 - .26 = 1.3$ gues (1.3×2.5×5,8×103)= 18,9×103 Watt and $f = \frac{1.89 \times 10^{-2}}{1515} = 3.66 \times 10^{-2}$ This waved be the limit for a cathode of this \$, value $R_{L} = \frac{1.3}{.58 \times 10^{-2}} = 224^{-100}$

7/23/08 assume an out put voltage 70.6 .6 To lave an efficing of .13 is.6 = .13.,515 6 = , 112, $I = \frac{.112 \times ...}{.079/ \times 10^{-4}} = 1.41 \times 10^{-4}$ = 10 4.048 See p 5 12.459 4.048 8,411×,307 = 2,58 The value of & must be 2.58 for this current to flow at this temp lut for this amount of current which is <u>112</u> = UZ = 19,3 then s=14 HU 14 X,133= 1.86

7/23/58 .6 + 1.86 = 2,46 2,58 2.40 .18 would have to be of which is impossiled. Let R_ = load resistance $IR_{L} = V$ $\frac{IR_L}{V_T} = S_0'$ Im the far $I^{2}R_{L} = P = I S_{0}^{\prime}V_{T}$ $\frac{TR_{L}}{V_{T}} = S_{0}'$ #1/1+ HAT A DE P= AFR V F FF & SKA

7/23/28 $\phi' = \phi_1 + S_R$ \$ - \$ = s_R = V_R - applied pot for V_T = space elan space elang Plot as in then . en. VR = SR PR J Power undercrit cond Pm = VRIM V= = 5' $P_w = VI$

7/23/58 10 as V decrean I increa and Pis may whether $\frac{dP}{dV} = I + \frac{dI}{dV} = 0$ $I = \frac{dI}{dv} \cdot \frac{d(lnI)}{d(lnv)} = 1$ de= d (ln I) - d (th) = 1 dlens) tak V=SVT $lnV = lns + lnV_{+}$ denI = Vr d(lnv) = d(lns) + 0 asseme Vf=.1 For 45=1, $\Delta ln = .1$ H = e' = 1.105tis would indicate that low I be plated as from the function of lows, to fund 45° points.



7/24/58 12 Log-log plot shows that rise mounent with decrease in were voltag Balances (slope 1) at 5. V-The difficulty is that zhis plat cannot apply as is lecause the clange that should be plotted is not concilly taken care of. Psu this slange being peotted Is this Vo that determin the powers. $V_0 + S_w V_T = V_R$ $dV_0 + V_T dS_w = 0$ $\frac{dV_0}{V_0} = \frac{V_T dS_W}{V_0}$ P=IVo dP = Idvo + VodI $\frac{dP}{dV_0} = I + V_0 \frac{dI}{dV_0}$

7/24/08 3 assume that 4 su) V7 then curve u= applies, Under the esitical space charge cond Current is Im and potential is VR. This condition is satisfied by $T_{m} = 9.664 \times 10^{-6} \frac{V_{7}^{3}}{\omega_{2}} = AT^{2}e^{-\frac{\phi}{V_{7}}}$ under the condition that \$ of this equation is \$, + nV_ with n >1. The applied potential is then $V_{OR} = \phi' - \phi_2$ and the power is $V_R I_m = P_R$ With 01V0 KVR power will increase to a max. as shown in general curves of pit for various values of V from 6 V_ to 18 V_. at Vom = R - Sm power out will be max, Vom = VR - Sm -

general equ. for power to load. P=Inter P= IV, Y $\frac{V_R - V}{V_T} = \sum_{k=1}^{\infty}$ $\frac{V_R}{V_F} = \sum_{i=1}^{V}$ $I = U^2 I_m$ $P = I_m V_r \quad U^2 \left(\frac{V_R}{V_r} - \xi \right)$ $= Im V_{T} \left[U^{2} \left(\frac{V_{R}}{V_{T}} - \Sigma \right) \right]$ When Z=0 $\frac{P_{R} = I_{m} V_{R}}{P_{R} = \sum_{V_{T}} V_{T}} = \left(\frac{F}{I_{m}} \right) \left(\frac{V_{R}}{V_{T}} - E \right)$ $\frac{V_{R}}{P = 0}$





1/24/38 16 From p (3) Sm -SW with VR known Smis known and $U_m^2 = I/I_m$ or I = Im Um Vom is known and P= Im Um Vom = Im Um (VR - SmV+) $P = I_m U_n V_R - I_m U_m S_m V_T$ $= I_m V_T \left(\underbrace{U_m^2 V_R}_{V_T} - U_m^2 S_m \right) = I_m V_T \left[\underbrace{U_m^2 V_m}_{V_T} \right]$ This is a function of VE





Review of development to here. (19) VR For a given cathodo temp and collector work - function there is a critical VR for zero space change at eve. surface. This condition is obtained if RR is in the externel circuit. R_{LR} = <u>V</u>_R and power P = V_RI_m as Ry is reduced, the current increases and the power is I'R, ; the output volts (IRL) = Vo and power IVo. There is a particular value of I and Kand: Run which gives the maximum power into the load. The larger the value of (VR/V2) the larger the Vom as shoron by curve I 40



For each value of Ve there is a particular Value of U'at the max of power output This is shown by euror I The power out is $P = I_m V_T \left[\frac{U_m^2}{W_T} \frac{V_m}{V_T} \right]$ This mult, factor is shown as III Then if VR = 10 The optimum value of Vom = \$ 4.9 The resulting " " Um = 3,75 7.7 and " " [] = 18.75 37.8 Fig 180 shows that that IJ = P' $P' = \mathcal{K} \left(\frac{V_R}{V_T} \right)^{2.16} = 1$ 37.8 18.75 = K. 10 2.00 $K = \frac{18.75}{575} = 3.26 \times 10^{-2},378$ $P_{moy} = I_{M} V_{T} \frac{378}{3,26 \times 10^{24}} \left(\frac{V_{R}}{V_{T}}\right)^{2,2E}$

2/ $I_m = 9.664 \times 10^{-6} \frac{V_7^{3/2}}{\omega^2}$ $P_{max} = \frac{3.14}{.14 \times 10} \frac{-9}{V_{T}^{2.5}} \frac{2.76}{V_{T}^{2.76}}, V_{R}^{2.76}$ $= \frac{3.72 - \frac{1}{2.76}}{3.14 \times 10^{7}} V_{7} \frac{1}{\sqrt{\frac{R}{2.76}}} \frac{2.76}{\sqrt{\frac{R}{2.76}}}$ Absume $V_{R} = 1^{\vee}$ and $V_{T} = 10^{-1}$ $V_{T} = ,31^{\vee}$ $P_{max} = \frac{3.14 \times 10^{-6}}{3.14 \times 10^{-7}} \cdot \frac{316}{1.82 \times 1} = 1800$ watts/m² $6.45 \times 10^{-10} = 1800$ watts/m² Radiation power (see 6) 3.26×10×(er) Hatts N+= 5.65 × 10-8 × (1,160) × (Er) = 5,65 × 1,81 × 10 + x ,3 = 3,07 × 104 $T = \frac{1800 \times 10^4}{3.07 \times 10^4} = 7.9\% 5.9\%$ If VR can der increased over IV 8= 29* R V_ = 1.5 to get 13% V=1,725

The diode as a heat - to electrical power transducer. mtroduction: Requirements) Low - w. f. col. 2) Small spacing 3) Sufficient Stemp. differed Interest without full consideration of fundamentals, Exponser 14, +K. Purpose - present basic relations details in T.E. not applied to specific application. Diode perpertus: Qualitative driensei-Energy diagram Emith col. F.L. Reser resestan load Fig 1



Computations for table 2 124

		(Vr - L)				1-1					
	1.2	1 for 4	+026	8		12	14		18	20.	
5	U	U	(v2)								
	1	0									
~	1 7	4		8 B		12		16 16			
1	2103	63	5 105	7 147	9 189	231	3 2.73	31.0	3.52	19 299	
2	3.37	6.6J	13.28	- 1992	8. 26. J.	33.2	39.8	46,5	53.1		
3	4.63	4,63	13,89	23,15		9		13	13		
24	6.05	0	12,1	24.2	36.3.	\$ 48.2	60.5	72.6	\$ 84.7	-96.8	
5	7,54		7.54	22,62	37.7-	52.8	67,9	82.9			
					<i>a</i>				iż.		
6	9.10		0	18,2	36.4	54.6	, 72.8	91.0	109.2	127.4	
7	10.77			10,77	32,3	53,9	75.4				
8	12,43			0	,24.9	49.7	,74,6	99.4	124.3	149.2	
	14.2				014.2	42,6	21.0	99.4	127.8	10156.2	
10	16,1				0	32.2	64.4	96.6	128.8	161,0	
						,		é	,	9	
11	17.9					0 17.9	53.7	39.5	125:3	(161.1	
12	19.9					0	39.8	379.6	-119.4	, 59.2	
13	21.9						021.9	65.7	109.5	152,3	
14	10.7						0	41.0	3 7216	51494	
15	16,00							PEIDS	10. 8	120,3	
	2815							0	×56.3	4 112 1	
10	2014							0	300	912	
10	22.5								o o	150	
19	347									347	
20	37 1									0	
	-1.1						2				
	Val		T	5	st .	parox =	and	112			
22	4 PVF		//	Chill	Amax	VT	Just	0			
	0		0	0	17	0	0	1			
	4		6.72	1.7	27	2.3	2.30	2,92			
	6		14.0.	2.72	318	3.28	3.28	4,27			
	8		24.4	3.80	501	4.2	4.20	5,18			
26	10		21.8	ViDS	644	4.9	4.95	1,64			
	12		50.0	6.5	SPI	216	5.6	7,10			
	14		agit	1.4	S.B.	6.0	0.6	12,15			
	16		17.5	0.60 G(C		1.4	8160	12.42			
	20		16/1	7660		911	9 50	16.95			
	20		101.4	10.42	CID M B	1-07	1,00	10.00			
			1				1				
							1.	nl, i	1-1-1-1		
			1	1	nete	ano	Non	and	•		
							~				







28 Derwation for Eq(9) $\frac{1}{7.729 \times 10^{-12}} \frac{T^{3}}{10^{2}} = AT^{2}e^{-\frac{9}{4}}$ $I = \frac{A w^2 T'^2}{7,729 \times 10^{-12}} = -\frac{P_R}{V_T}$ See Sect 50 for a = Ave To $\overline{\Phi} = \phi_{\nu} + \nu V_{\overline{\tau}}$ $a = \frac{A}{7.729 \times 0^{12}}$ $\frac{12 \times 10^{6} \cdot 1.649}{7.729 \times 10^{-12}} = 10^{17.408} \\
= 10^{17.408} \\
= 10^{17.408} \\
= e^{40.09}$ $40.09 + 2 hww + \frac{1}{2} lnT_0 = \frac{p_R}{V_T} + \frac{1}{2}$

assume To ~ 1500 K. 1000 In To = 7.3 - 2 ln To = 3,65 3.45 40.09 43,74 ,5 43,24 43. V_ = _____ V_ = _____ 43,2 + 4.6 logo W assume To = 1000 VT = - PR 43.0 + 4.6 logo W

30 Temperalue of collector. Collector emission should be about $e^3 \times I_1 = \begin{bmatrix} I_1 \\ 20 \end{bmatrix}$ $\phi_2 = \phi_R - V_R$ $I_{1} = I_{m} e^{X} - \begin{bmatrix} \psi_{1}^{2} & \psi_{2} \\ \psi_{1}^{2} & \psi_{2} \\ \hline U_{1}^{2} & \psi_{2} \\ \hline U_{1}^{2} & \psi_{2} \\ \hline U_{2}^{2} & \psi_{2}^{2} \\ \hline U_{2}^{2}$ $7.729 \times 10^{-12} \frac{T_{1}}{L_{02}} e^{x} = A \bar{e}^{3} T_{2}^{2} e^{-V_{R}}$ Ploton 31 $\frac{3fous(\underline{T})}{(\underline{T}m)} = 1 + 0.29(\frac{V_R}{V_T})^{1.36}$ $\frac{9.664 \times 10^{-6} \frac{V_T}{W_2}}{\omega^2} \cdot \left[1 + 0.29(\frac{V_R}{V_T})^{1.36}\right] = AT_2^2 e^{\frac{V_R}{V_T}} \cdot \frac{1}{V_T}$

31 $\left(\overline{U}^{2}-I\right) = \left(\underline{V}_{e}\right)$ EUGENE DIETZGEN CO. $6.64 = k_1 0^{1/36} = k \times 22.9$ 0.29 × $\left(\frac{V_{12}}{V_T}\right)^{1/36}$ 6,64= \$ 103 $k = \frac{664}{20.54} = .302$ $V = 1 + 0.31 \cdot \left(\frac{V_{P}}{V_{e}}\right)^{\frac{1}{3}}$ ND. 340-L22 DIETZGEN GRAPH PAPER LDGARITHMID-2 GYGLES X 2 GYGLES 19.1. 51,36 $U^{2} = 1 + 0.29 \left(\frac{V_{R}}{V_{T}}\right)^{1.3C}$ A./ 5

 $\frac{\frac{4}{6}}{\frac{120\times10}{20\times9.66\times10^{-6}}} = \frac{6.2}{9.794}$ = 10 PR - VR $V_{T2} = -\frac{1}{22,56 + 2 \ln T_2 + 2 \ln W - 1.5 \ln V_7 - \ln [I]}$ To essenced as 1020 29 JR Into Epample. Take \$ = 1.2 VT2 = 112 22,5% + 14 - 21.14 + 3,06 - 1,47 $W = 2.54 \times 10^{-5} = 10^{-4.595} = 10.57$ Vy=13 Take VE = 6 $\frac{\ln (1+7=1.47)}{\sqrt{1-1}} = 0.07 \text{ or } 1-\frac{870}{17}$

with Ty at \$20 $V_{T2} = \frac{1.2}{16.4}$.073 or 850 °K 840 is best value. $\frac{\varphi_2 + V_7 2}{V_T} = N$ $NV_{+} = (H-2)V_{+} = \phi_{2}$ $V_{T2} = \frac{p_2}{22.56 + 2 \times \ln 1000 + 2 \ln \left(\frac{T_2}{1000}\right)}$ $\frac{13.82}{2}$ 36.38 $\frac{\phi_2}{36.38 + 2\ln(\frac{T}{1000}) + 2\ln W + 1.5\ln(\frac{T}{1}) - \ln T}$ VTZ=
34 Numerica estample $T = 1510^{\circ} K, \quad ln T = 7.3 \quad \pm ln T = 3.65$ $V_{T} = .13 \quad V_{T}^{'2} = .361 \quad V_{T}^{'3/2} = .0469 V$ $V_{T}^{-1} = 7.7$ log₁₀ 7.7 = .8865 $W = 2.54 \times 10^{-5}$ log₁₀ W = -4.595 $W^{2} = 6.45 \times 10^{-10}$ 2 ln W = - 21.15 3959 3.65 43,24 21.1522.09 $22.09 \times .13 = \phi_R = 2.87$ $2.87 - 1.57 = 1.3 = V_R$ $\frac{V_R}{V_T} = 10.75$ $F_{max} = \frac{3.67 \times 10^{-6} \times .361 \times 1.69}{6.45 \times 10^{-10}} = 3,470 \text{ Wattle}/m^{2}$ f = 2.87 - .13.204 = 2.6 $F = \frac{3.470}{15} + \frac{3.470}{5} + \frac{3.67 \times 10^{-10}}{5.45} = 702$ $F = 14.1 \times 10^{3}$ I = 702 × 7.73 = 5,426 a/m2

35 To get an increase in current of 7.73 pot max must change 2,04 V7 = ,267. and I is 5,05 on Velowgers, 656 this 1.3-,66 = .641 = Vo <u>3470</u> = 5400 a/m2 ascumut, Radiation power 3xro - W/m 2 See 20 8 = /3.4/ × 10 - All $T_{Q4}^{255} = \frac{3.5}{36,38 + 4.6 \times 4.6 + 3.45 \times .887 + 2.3} \xrightarrow{X+}_{.885} + 1$ 11600 × 1.57 Ve = ,773 36.38 3.06 Tc = 920 %. 2.03 41,49 21,17 20.30

36 Incalculating Powelows or Jaci of emitter. wetan $N_{f} = 5.65 \times 10^{-8} ((1570)^{4} - (920)^{4}) Er$ Clechor $(1.51) \times 10^{12} = 5.20$ $(1.51) \times 10^{12} = 5.20$ $(.92)^{4} \times 10^{12} = .724$ $(.92)^{4} \times 10^{12} = .724$ $(.44)^{10} = .7.1 \times 10^{4}$ $f_{1,4,8}$ $f_{1,4,8}$ for, 25= Er N==6,3×104 $h \frac{.347 \times 10^{-1}}{7.1} = 4.9\%$ Cathode w.f. (VR-V- [In = +]) 14 Rad 83% + El. 17%-

3.086 2nd Numerical Elamp T= 1219°K . ht= 7.107 \$ luf = 3,5535 $V_{f} = .105$ $V_{f}^{r_{2}} = .324$ $V_{f}^{3r_{2}} = .0340$ V-- = W= 7.54×10-5 39.59 3.55 43.14 21.15 $22 \times .105 = p_{R} = 2.31$ 22.00 2,31 - 1.57 = ,74 = VR $\frac{V_R}{V_T} = 7.05$ Pmax = 3.67×10⁻⁶ × .324× .547 = 1,010 Watter/m² 6.45×10⁻¹⁰ = 1,010 Watter/m² $T_{\rm M} = \frac{9.66 \times 10^{-6} \quad 3.4 \times 10^{-2}}{6.45 \times 10^{-10}} = 509 \, a/m^2$ $\frac{I_{m}}{m} = \frac{1 + .29 \times (2.05)}{14.2} = 5.12$ I = 2600 a/m2

38 11600×1.57 Tc= 36.38-4,6×4.6 +3,45×,886 +2,3×,71 3,06 36.38 3.06 Take Te = 800 1.63 41,07 Vie = 0806 21,57 19.50 Tc= 850°K, -15 Pr= 5.65 x 10 (2,21×10 x -.28 2,21 152 1.79× Pr= 5.68 × 1.7 ×,25 104 22.4 = 2.41×104 $\int = \frac{1010 \times 10^3}{.241 \times 10^3 \times 10^2} = 4.2\%$ $q_{1} < \frac{2,31 - 2,64 \times ,105}{\frac{.78}{2,03}} =$

Workout care for 1740% VT=15 T = 1740 lnT = 7.46 $\frac{1}{2}$ lnT = 3.73 $V_{T} = 1.5$ $V_{T}^{'12} = .387$ $V_{T}^{'3/2} = .058$ V7 = 6.67 log. 6.67 = , 824 39.59 3.73 43,32 27.17 ×.1.5 = 3,33 = P.R. 22,15 $\frac{1,57}{1,78} = V_{R}$ $\frac{V_{R}}{V_{T}} = 11.87.$ $\frac{V_{R}}{V_{T}} = 3.17$ $P_{max} = \frac{3.67 \times .387 \times 3.17 \times 10^4}{6.45} = 6,980$ $T_{m} = \frac{9.66 \times 10^{-6} \times 5.8 \times 10^{-2}}{6.45 \times 10^{-10}} = 870 \ a/m^{2}$ $\binom{v_R}{v_r}^{3} = 27.1$ 27.1 ×.31 +1 = 9.4 = U^2 2.3 log 10 0 = 2,24 3,244,15 I may = 8180 a/m2 Vo = .854 11600 × 1,57 Te= 36.38 - 4.6×4.6 + 3.45×.824 + 2.24 Ø= 2,84 36.38 VTC = .78 V 41.46 Te= 920 ~

 $T^{5} = \frac{15.9 \times 10^{15}}{15.2}$ $P_{r} = 1.4 \times 10^{-12} \times 15.2 \times 10^{16} = 2.13 \times 10^{5}$ 40 6.98×10³ =.0328 2.13×105 3,3 % use this formula, for $T = 1510 \qquad T_{c} = 920$ $T^{5} = 7.87 \times 10^{15}$ $\frac{7}{7.17 \times 10^{15}} \qquad P_{r} = 10 \times 10^{4}$ J = 3470 = 3,5% TE = AVO T=1220 TJ = 2,7×10.15 .44 2,26 PC = 3,16×104 J = 1010 = 3,2%

analysis applies to Hatsopoulos + Kaye Stefan Boltzmann low 0 = , 5668 × 10 + eig cm² deg 4 sec. 10° ergri I watt ,5668 × 10 Watts / cm 2 deg 4 ,5668 × 10 " 1 m / dug . K 5,668 × 108 V T= 1510% TY = (1.51) × 1012 = 5,2 × 10 × 5.6 × 10-8 = 29.1×107 watts assunde E, = E, = . 4 (2,5+2,5-1)=,25 29.1×104×.25= 7.3×104 = 73 × 103

Hork 2 Take (Vo) max = . 6 V12=,365 1550 > V7 = . 1335 V V7 - 0 488 assunae VI = 2×10 - 5 m. ??) log W = - 4.7 Shiw = 10,8 2/nw=-21.6? lnT= 7.34 ~ 2 lut = 3.67 / 39.59 3.67 4326 PR = . 1335. (21.66) 21,6 21,66 ₹ 2,89 Take V_R= 1.1 V_R = 8.25 with $V_R = 9$ $V_R = 1.7$ Pmax = 3.7 × 10 × 366 × 1.44 4×10-10 $= .49 \times 10^{4}$ = 4.9 × 10³ Vo =.6 Imax = 8150

HXK with I may 8150 Im - 9.66×10 × 4.88×10=2 4×10-10 = 1180 OK U2= 8.15 = 6.9 1+,31×(9) = 6,85 formula(11) 2×10 = Since Im = 1180 ØR = V_ (14 + 14.7 - 7.55) $ln \frac{1180}{T^2} = ln A - \frac{\varphi_R}{V}$ 28.7 21.15 PR = 2.72 VR = 1.2 Ø2= 1.52 $\phi' = 2.72 - .1335.1.93$ \$ = 2,46

HAK 4 Election costing power, 8150 (2,46+,267) = 2,22,×10 W/m2 assumy this loss. Eff = 4.9×103 = 22% H. JK show 13% at 1550 With W=2,54x0 Pmax = 3750 m/m26 Since eff x May ". $\frac{3750}{3,7\times10^{-6}\times1.365} = \frac{V_R}{W2} = 2.78\times10^9$ With 3750 = Imax= 6250 a/m2

Radiation from O

173 ×10 5 111 184

 $\frac{3.750 \times 10^3}{184} = 4.5\%$

 $\frac{3,750 \times 10^{3}}{13 \times 10^{2}} = .289 \times 10^{5}$ At This we we have taking by Hok

HJK 5

assume Pmar = 4200 Imax = 7000 \$= .1325(28.7 - 8,85) = 2,52 2,52+,267 = 2,79 2.79× 7.000 = .195×105 4,200×03 ·195×05 = 21.5%

47K 6 Imax 0.6 = Pmax = . 13 × Imax (\$ +,27) \$ +. 27 = 4.61 \$ = 4.3 which is impossible high malculating effmax = 130% H+K must have used other losses m addition to Imay (\$ +. 27) election cooling leut did not use the radiation power loss. Questions'-1) are the timperating guorated true temp or brightness temp? How 3) What was the observed current at max? 3) What values of 5, E, and Ez in Measured? eq. 7 wereused? 4) How do they justify statement that elec. cooling is main term of Eq.(6.) 5) Frawdo they prove Eq (7)?

The Thermionic Diode As a Heat-to-Electrical-Power Transducer *

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Abstract

The high-vacuum thermionic diode is shown to be capable of converting heat to electric power. For this purpose, a low work-function collector, a small spacing, and sufficient temperature difference between the emitter and the collector are necessary. A detailed understanding of both thermionic emission and space-charge phenomena are needed for evaluating the effectiveness of this transducer. With V_R defined as the critical bias potential that gives zero potential gradient at the collector, the maximum available power is given by the relation $3.7 \times 10^{-6} V_T^{1/2} (V_R^2/w^2)$ watts/m². Here, V_T is the voltage equivalent of the temperature T/11,600. In the range of emitter temperature from 1200°K to 1700°K, the most optimistic conversion efficiency lies between 3 and 4 per cent for a diode of 0.001 inch spacing. With a suitable choice of emitter inhomogeneity, the introduction of cesium vapor should improve the efficiency of this device.

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INTRODUCTION

It has been known since the earliest experiments on thermionic diodes that heat can be converted into electric power by this device. Three requirements must be satisfied for it to yield a significant amount of power: (1) a low work-function collector; (2) a small spacing between the emitter and the collector; and (3) a sufficient temperature difference between the emitter and the collector.

Hatsopoulos and Kaye¹ have given a brief discussion of the physical phenomena involved, but they have omitted so much that is basic to the understanding of the problem that a more detailed analysis is justified. It is the purpose of this paper to summarize the fundamental relations that were developed and published under the title of "Thermionic Emission,"² referred to below as T. E. The requirements that must be satisfied for the device to have its highest efficiency will be developed by means of these theories.

DIODE PROPERTIES

Although the equations used in this paper apply strictly to the planeparallel structure, the methods by which they can be applied to a concentric cylindrical structure are given in Sections 60 and 61 of T. E.

If the collector surface potential of a diode structure is made very negative with respect to the emitter, the electron flow is not inhibited by space charge. As the collector potential is made less and less negative, the presence of space charge creates a critical situation for which the potential gradient at the surface of the collector is <u>exactly zero</u>. Under this condition there is no net charge on the surface of the collector, whereas at the surface of the emitter there is a positive surface charge equal to that of the total number of electrons in transit between the emitter and the collector.

-2-

The potential distribution under this critical condition is illustrated by Fig. 1. Some of the symbols that are used in the following equations are also defined in this figure. The "true work-function" of a surface is the energy difference for an electron at the Fermi level (FL) within the conductor as compared with its energy in the immediate neighborhood of the surface of the conductor in the absence of an externally applied field. This work-function is not a constant; it varies with the temperature and the surface condition. It should not be confused with the "Richardson work-function," which is often misidentified with the true work-function.

In Fig. 1 the true work-functions of the emitter and of the collector are shown as ϕ_1 and ϕ_2 , respectively. The Fermi levels are separated by the potential, indicated by V_R . Note that this <u>critical</u> energy separation applies to the present problem when the potential gradient at the collector is exactly zero. This quantity (V_R) becomes the determining factor in establishing the effectiveness of the device as an energy transducer. If the energy difference ϕ_R^* is greater than the work-function ϕ_1 by at least V_T , as defined by Eq. (1), the current that flows across the diode is independent of the emitter workfunction.

$$V_{\rm T} = \frac{k}{q} T = \frac{T}{11600}$$
, (1)

where k is Boltzmann's constant, the value of the electronic charge is q, and the temperature (in degrees Kelvin) is T. The equation that was derived in Section 43 of T. E. to relate the maximum current flow to the spacing, w, and the temperature is given as

$$I_m = 7.729 \times 10^{-12} \frac{T^{3/2}}{w^2} = 9.664 \times 10^{-6} \frac{V_T^{3/2}}{w^2}$$
 (2)

The simplest circuit arrangement for delivering electric power to an external load resistance is shown in Fig. 2. For an emitter of area A, there

-3-

is a critical value for the external load resistance (R_{LR}) which will bring about the potential distribution illustrated in Fig. 1. This load resistance must satisfy

$$R_{LR} I_m A = V_R.$$
 (3)

If a resistance (R_L) is used smaller than this critical value, the current density flowing across the diode will be greater than I_m , and the energy difference between the Fermi levels will be less than V_R . As the resistance decreases, the voltage across it decreases but the current increases more rapidly at first until an optimum resistance is reached. The product VI therefore comes to a maximum and more power is delivered to the load when a space-charge minimum exists between the emitter and the collector. The potential distribution under this condition is illustrated by Fig. 3, in which the dotted lines represent a superposition of Fig. 1 on Fig. 3. The fact that the drop in potential over the load resistance has been decreased is shown by the difference between V_R and V_0 . The space-charge minimum at ϕ' is lower than that at ϕ'_R . The increase in the current that flows around the circuit is determined quantitatively by this change as exp $(\phi'_R - \phi')/V_T$. The method of determining the optimum load conditions will now be discussed.

QUANTITATIVE EVALUATION OF DIODE PROPERTIES

The detailed analysis that is given here is subject to the condition that ϕ' exceeds ϕ_1 by at least V_T . (See Table 9 of T. E. for data on the special, and rather unusual, case in which the difference $(\phi' - \phi_1)$ is less than V_T). The basic table (Table 8 of T. E.) upon which the correct analysis of the problem depends is given here in a shorter form as Table 1. The data of Table 1 are plotted as curve 1 in Fig. 4.

-4-

The power delivered to the load for any value of current that is greater than I_m , and for any value of V/V_T that is less than V_R/V_T is expressed by

$$P = I_m V_T \left[\frac{I}{I_m} \left(\frac{V_R}{V_T} - \Sigma \right) \right] = I_m V_T T T$$

(4)

The quantity \sum is defined as $(V_R - V)/V_T$. For an arbitrary set of values of V_R/V_T between 4 and 20, the quantity within the square brackets (Π) has been computed, and corresponding curves are plotted as a function of \sum in Fig. 4. The curves are to be used for determining the value of \sum which is associated with the maximum of each curve, and for illustrating that deviations from the maximum of from 10 to 20 per cent do not result in much loss in operational efficiency. Table II summarizes the relations between the significant quantities at the several maxima. The quantity \prod_{max} is defined as

$$\mathbf{T}_{max} = \frac{P_{max}}{I_m v_T}$$
(5)

The output voltage is V_0 , at the maximum of the curve.

Curves I and II of Fig. 5 represent the data for \sum_{max} and (I_{max} / I_m) of Table II in graphical form for easy interpolation. Figure 6 shows the relation between \mathbf{T}_{max} and $\mathbf{V}_{R}/\mathbf{V}_{T}$. A logarithmic plot of these data is used to illustrate how \mathbf{T}_{max} is related to the important parameter $(\mathbf{V}_{R}/\mathbf{V}_{T})$. The equation for the straight line is given by

$$\pi_{\text{max}} = 0.385 \left(\frac{v_R}{v_T}\right)^2$$

-5-

(6)

MKS units are used in all of the equations that are given above, current densities are expressed in amperes/m², and the power is expressed in watts/m².

DISCUSSION OF RESULTS

The combination of Eqs. 5 and 6 yields

$$P_{\text{max}} = 3.7 \times 10^{-6} V_{\text{T}}^{1/2} \frac{V_{\text{R}}^2}{w^2}$$
.

Although V_R is dependent upon temperature through its relation to ϕ_R^i , it is clearly shown in Fig. 1 that the work-function of the collector ϕ_2 and the spacing w are the most important controllable factors.

The design procedure that must be used is outlined in the following steps:

1. Choose the smallest possible value of the spacing w which is consistent with the reliable fabrication of the diode.

2. Specify the necessary power per unit area of the emitter for the device to be useful.

3. Assume an approximate value for $V_{\rm T}^{1/2}$ of 0.35 to 0.4 and compute the value of $V_{\rm R}$.

4. Estimate the lowest possible collector work-function ϕ_2 that can be realized in the diode and determine the value of ϕ_R^i from

$$\phi_{\rm R}^{\prime} = \phi_2 + v_{\rm R} \,. \tag{8}$$

(7)

5. Use the following equation as a means of determining the minimum emitter temperature that can be used to satisfy the requirements:

$$\frac{T}{11600} = V_{T} = \frac{\phi'_{R}}{39.59 + \frac{1}{2} \ln T + 2 \ln w}$$
(9)

-6-

A simplified form of Eq. (9) that applies if the emitter temperature is close to 1500° K is

$$T = \frac{11600 \not P_{\rm R}^{1}}{43.2 + 4.6 \log_{10} w}$$
(10)

If a specific application depends on having an emitting source at a specified temperature, then the reverse of these steps can be followed; that is, p_R^i is first determined from Eq. (9) or Eq. (10). Equation (8) determines V_R and Eq. (7) the maximum power that can be delivered to the load.

Once $(V_R^{}/V_T^{})$ is known, the diode current density $(I_{max}^{})$ at the maximum power output can be determined by

$$\frac{I_{max}}{I_{m}} = U_{max}^{2} = 1 + 0.31 \left(\frac{V_{R}}{V_{T}}\right)$$
(11)

With the maximum power output P $_{max}$ known from Eq. (7), the optimum load resistance for an emitter of area A becomes

$$R_{\rm LO} = \frac{P_{\rm max}}{I_{\rm max}^2 A}$$
(12)

Since minimizing the collector work-function results in a greater power output, it is necessary to maintain the collector at a sufficiently low temperature so that its saturation electron emission will be small compared with the electron current that it receives from the high-temperature emitter. The following formula serves as a means of evaluating this maximum temperature in terms of quantities already determined by the previous analysis and based on the assumption that the emission from the collector will be approximately 5 per cent of the electron current received from the emitter.

$$T_{c} = \frac{11600 \ \phi_{2}}{36.38 + 4.6 \ \log_{10} \frac{T_{c}}{1000} + 4.6 \ \log_{10} w + 3.45 \ \log_{10} v_{T}^{-1} + 2.3 \ \log_{10} v_{max}^{-2}}{1000}$$
(13)

NUMERICAL EXAMPLES

In order to illustrate the use of the aforementioned equations, two of the critical quantities will be taken arbitrarily. These are 1.57v, for the true work-function of the collector, and 0.001 inch, as the spacing between the emitter and the collector. The values of the assumed emitter temperatures are given in Table III, together with the derived results.

If the area of the emitter is actually 1 sq. cm. and the temperature is 1510° K, then these results show that it is possible to deliver to a load resistance of 1.2 ohm electric power of 0.35 watt. The natural question to ask is "What is the efficiency of this conversion of heat to electric power?" In answering, we note that the <u>absolute maximum</u> of efficiency would occur if there were no losses except radiation losses from the emitter to the collector. It is obvious that in any practical application there will be other losses such as radiation losses to heat shields, and the electron cooling of $I(\phi'+2V_T)$, which will reduce the actual operating efficiency below the most optimistic figure. The radiation loss from the emitter to the collector can be estimated by using

$$P_r = 5.65 \times 10^{-8} (T^4 \overline{\epsilon} \ \overline{r} - T_c^4 \overline{\epsilon_c} \ \overline{r_c}) \text{ watts/m}^2.$$

(14)

In Eq. (14), $(\overline{e} \ \overline{r})$ is closely related to the "total emissivity" of the emitter and to the reflectivity of the surface. It is not independent of

-8-

temperature. The determination of \overline{e} \overline{r} involves a problem of multiple reflection between two surfaces of different spectral emissivity, and hence a very complex integration is needed to determine it. The same difficulty is associated with the quantity $\overline{e_c}$ $\overline{r_c}$ as it applies to the collecting surface. For a limited range of temperature, it will be assumed that

Sels part + p 10

$$\epsilon r = 2.5 \times 10^{-4} T.$$
 (15)

a put in ly for .

With these approximations we have

 $P_r = 1.4 \times 10^{-11} (T^5 - T_c^5) \text{ watts/m}^2.$ (16)

This formula was used to calculate Pr and (eff)max of Table III.

CONCLUSIONS

This analysis has shown that a conversion of heat energy to electric power is quite possible in a high-vacuum diode, although many technical difficulties stand in the way of creating an efficient power transducer of this kind. The calculations show that the maximum efficiency is almost independent of the temperature, since V_R increases approximately as $T^{2\cdot3}$. Equation (7) would then give the maximum power as proportional to $T^{5\cdot1}$. Since the radiation power also increases almost proportionally to T^5 , the efficiency remains constant. The efficiency of 3.5 per cent that is given here is undoubtedly optimistic by at least a factor of two. All other things being approximately equal, the reduction of the emitter-to-collector spacing a factor of three increases the efficiency by almost a tenfold factor. This decrease in spacing would be extremely difficult to accomplish, since it would indicate a spacing of 0.0003 inch. The diode power transducer not only involves a proper application of the theories of thermionic emission but also the theory of space charge. Some of the difficult technical problems could be relieved by the design of a diode containing cesium vapor. Cesium atoms, as they come in contact with the emitter at a temperature higher than 1200° K, become ionized³, leave the emitter and then flow into the electron space-charge region. To use this type of ionization and still have an average emitter work-function of less than 2.5 v would demand a "controlled" inhomogeneity on the surface. With such an emitter many electrons are permitted to go to the collector that could not otherwise do so. Furthermore, the presence of cesium on the cooler collector reduces its work-function and makes it a favorable electron receiver for a power transducer. The basic facts for predicting in detail the efficiency of this device are not available at this time.

REFERENCES

1. (G. N.	Hatsopoulos	and	J.	Kaye,	J.	Appl.	Phys.	29,	1124	(1958).
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- W. B. Nottingham, "Thermionic Emission," Handbuch der Physik, Vol. 21, 1, (1956), Springer Verlag, Berlin-Gottingen-Heidelberg.
- 3. I. Langmuir and K. H. Kingdon, Proc. Roy. Soc. (London) Al07, 61 (1925).

	The Diode Characteris	stic With \sum =	$(v_{R} - v)/v_{T}$ *
Σ	ı/ı _m	£	I/I _m
0	l	5.02	7.57
0.565	1.59	7.44	11.51
1.28	2.41	9.75	15.6
1.65	2.86	13.10	22.1
2.31	3.69	15.28	26.6
2.90	4.48	17.44	31.3
3.73	5.65	23.84	46.3

Table I

*Abridged from Table 8 of "Thermionic Emission."

		Drawy or typed	Prot	Stides			
1		-	1				
2		1	1				
3		1	/				
4		~	1				
5		1	1				
6		1	/				
7		~	1	/			
8		~	1				
9		V	~				
/ D		V	~				
11		~	~				
ir		~	/				
13		1	/				
14	a	~	1				
15	h	/					
16		V	~				
17							

Table II

a

Date Derived from the Maxima of Curves in Fig. 4

$\frac{v_{R}}{v_{T}}$	Σ_{max}	TTmax	Imax Im	$\frac{v_{R}}{v_{T}} - \sum_{max}$	$\ln (\frac{I_{max}}{I_m})$
	curve I Fig. 5	Fig. 6	curve II Fig. 5	$(v_0^{\prime}/v_T^{\prime})$	
0	0	0	l	0	0
4	1.70	6.72	2.92	2.3	1.07
6	2.70	14.0	4.24	3.3	1,44
8 .	3.80	24.4	5.80	4.2	1.76
10	5.05	37.8	7.73	4.95	2.05
12	6.30	55.0	9.70	5.7	2.27
14	7.40	75.8	11.5	6.6	2.44
16	8.6	99.5	13.45	7.4	2.60
18	9.6	129.0	15.35	8.4	2.73
20	10.4	161.4	16.80	9.6	2.82

		Table III		
Calculations	for Diode: w	= 2.54 x 10 ⁻⁵ m	; \$\$\phi_2 = 1.57 v; \$	area A.
VT	,105	.13	,15	0
T	1220	1510	1740	Units K
ØR	2.31	2.87	3.33	volt
v _R	0.74	1.3	1.78	volt
v _R /v _T	7.0	10	11.9	
Pmax	1000	3470	7000	watt/m ²
Im	509 1612	702	870	a/m ²
Imax	2600	5400	8200	a/m ²
vo	0.385	0.64	0.854	volt
RLO	$1.5 \times 10^{-4}/4$	A 1.2 x 10 ⁻⁴ /A	1.04 x 10 ⁻⁴ /A	ohm
Tc	850	920	920	°K
$(\phi_1)_{\max}$	2.0	2.5	2.8	volt
Pr	3.16 x 10 ⁴	10 x 10 ⁴	21.3 x 10 ⁴	watt/m ²
(eff) _{max}	3.2	3.5 (3.0 #)	3.3	per cent
Pa	557 × 104	141×10	2 AFX OF	
	17	1,67	2:75	
φ	2.14	2.605	2.99	
	2.31	1265	3.33	
	2,14	2,605	2.99	

3.16 in 3.93 11.67 24.0

-14-





Potential distribution with critical condition of zero gradient at the collector.





Transducer circuit.





Potential distribution with maximum power in load.



Fig. 4

Values of $\overline{\Pi}$ as a function of Σ for selected values of $(\mathtt{V}_R/\mathtt{V}_T)$ of 4 to 20 and curve I is (I/I_m) of Table I.





Values of Π_{max} as a function of V_R/V_{Π} . The straight line representation of the data is Eq. (6).



Calculations on data in H+K- IRE paper. V_R = ,79 for 1538% V/2=.364 V/3/2 = 48 ×10 $V_T = , 1325$ $Im = \frac{9.66 \times 10^{-6} \times 48 \times 10^{-3}}{10^{-10}} = .464 \times 10^{4}$ Inobserved . 465 × 104 or w=.0010 cm assin VT 2= , 7/66 VT =/.1325 $\frac{0.1}{10} = \frac{9/66 \times 49 \times 10^{-9}}{10} = \frac{10}{10} = \frac{10}{10} \times 10^{-9}} = \frac{10}{10} \times 10^{-9} = \frac{10}{10} \times 10^{-9} \times 10^{-9} = \frac{10}{10} \times 10^{-9} \times$ Cal. Imax = 47×104 (1+.31×10,7)=.47×10× 4,3 (=1) = 2.02×10 $P_{max} = 3.7 \times 10^{-6} \times .364 \times (.79)^{-7} = .84 \times 10^{-10}$ 10-10 Vo= ,416
ψ _c	xc ²	$\left[\mathbf{F}(\boldsymbol{\psi}_{\mathbf{C}})\right]$	$\left[\mathbf{F}(\psi_{c})\right]^{3/4}$	$\left[F(\psi_{c})\right]^{3/2}$
.01	.02074	.08849	.16227	.02633
.02	.04215	.1420	.23132	.05351
.03	.06396	.1875	.28494	.08119
.04	.08602	.22846	.33045	.1092
.05	.1084	.26654	.37094	.1376
.06	.1311	.3025	.40792	. 1664
.07	.1540	.3369	.44215	. 1955
.08	.1772	.3698	.47424	. 2249
.09	.2004	.4015	.50438	. 2544
.10	.2240	.4324	.53320	. 2843
. 15	.3441	.5757	.66091	.4368
. 20	.4680	.7067	.77078	.5941
. 25	.5951	.8295	.86914	.7554
. 30	.7251	.9462	.95937	.9204
. 35	.8578	1.0584	1.0436	1.089
.40	.9930	1.1672	1.1229	1.261
.45	1.130	1.2716	1.1975	1.434
.50	1.270	1.3748	1.2696	1.612
.60	1.555	1.5736	1.4050	1.974
.70	1.847	1.7649	1.5312	2.345
.80	2.146	1.9542	1.6505	2.724
.90	2.455	2.1334	1.7652	3.116
1.00	2.766	2.3101	1.8738	3.511
1.10	3.084	2.4840	1.9786	3.915
1.20	3.408	2.6550	2.0799	4.326
1.40	4.072	2.9896	2.2735	5.169
1.60	4.757	3.3163	2.4574	6.039
1.80	5.457	3.6338	2.6319	6.927
2.00	6.180	3.9482	2.8009	7.845
2.20	6.917	4.2560	2.9631	8.780
2.40	7.667	4.5583	3.1196	9.732
2.60	8.433	4.8559	3.2711	10.70
2.80	9.217	5.1538	3.4205	11.70
3.00	10.011	5.4463	3.5651	12.71
3.20	10.824	5.7367	3.7068	13.74
3.40	11.649	6.0243	3.8453	14.79
3.60	12.482	6.3072	3.9799	15.84
3.80	13.330	6.5908	4.1134	16.92

Collector Region Potential and Its Relation to Emitter Properties and Current Flow. (Use with Eq. 46-2 and related equations.)

(Continued on next page)

Table 5

Eg 9 $\phi_R = .132 (39, 59 + \frac{7.35}{2} + 2(-11,5))$ 3959 3.68 43,27 23.0 20,27 ×, 1325= 27 $\phi_2 = 2.7 - .79 = 1.91^{\vee}$ See Heat Transmission W.H. Mcadams See Chapt + by Hottle p 55 Formuld for greg bodie $\begin{aligned} & \mathcal{F}_{1=2} = A_{1,0}(T_{1,1}^{*} - T_{2,1}^{*}) \frac{1}{\overline{\varepsilon}_{1,1}^{*} + \overline{\varepsilon}_{2,1}^{*} - 1} \\ & \text{ly infinit Derivs} \end{aligned}$ Colculation

ψ _s	Z	z ²	u _o	u _o ²	(I ₀ /I _m) ^{1/2}	I _o /I _m
3.0 3.1 3.2 3.3 3.4 3.5 3.6 3.8	.8749 .8804 .8870 .8920 .8976 .9031 .9075 .9164	.7654 .7751 .7868 .7957 .8057 .8156 .8236 .8398	4.482 4.712 4.953 5.207 5.474 5.755 6.050 6.686	20.09 22.20 24.53 27.11 29.96 33.12 36.60 44.70	3.922 4.148 4.393 4.644 4.913 5.197 5.490 6.127	15.38 17.21 19.30 21.57 24.14 27.01 30.14 37.54
4.0 4.2 4.4 4.6 4.8	.9247 .9319 .9380 .9441 .9496	.8551 .8684 .8798 .8913 .9017	7.389 8.166 9.025 9.974 11.023	54.60 66.69 81.45 99.48 121.51	6.833 7.610 8.465 9.416 10.47	46.69 57.91 71.66 88.67 109.6
5.0 5.5 6. 7. 7.5	.9546 .9646 .9723 .9784 .9834 .9834 .9873	.9113 .9304 .9454 .9573 .9671 .9748	12.18 15.64 20.09 25.79 33.12 42.52	148.4 244.7 403.4 665.1 1096.6 1808.	11.63 15.09 19.53 25.23 32.57 41.98	135 2 227.7 381.4 636.7 1060.5 1762.4
8 9 10 12 14 16	.9900 .9939 .9961 .9983 .9994 .9994	- 9801 - 9878 - 9922 - 9966 - 9988 - 9988	54.60 90.02 148.4 403.4 1096.6 2981.	2981. 8103. 22026. .16275 × 106 1.2026 × 106 8.8861 × 106	54.05 89.47 147.8 402.7 1096. 2979.	2921.7 8004. 21854. .1622 × 10 1.201 × 10 8.875 × 10
					and the second sec	

Emitter Region Potential and Its Relation to Emitter Properties and Current Flow. (See Sections 43 and 44 and Fig. 9.)

Note 1. Ψ_s and χ_s from Table 3E.

z = (χ_{s}/χ_{m}) from Eq. 43-7. $u_{o}^{2} = I_{o}/I_{R} = e^{\psi_{s}}$ from Eq. 43-5. $(I_{o}/I_{m}) = z^{2} e^{\psi_{s}}$ from Eq. 43-6.

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	2	Z. tee	L Phys	130-	135 (190	+1)
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		Z. fee	L Phys	130-	135 (190	+1) 112 112 112 112 112 112 112 112 112 112
out the second		Z. tee	L Phys	130-	135 (19)	+1) (1+1) 1000 1
00 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		Z. fee	L Phys	130-	135 (19)	41) 100 100 100 100 100 100 100 1
1000 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		Z. tee	L Phys	130-	135 (190	+1) 1308 5100 5100 5100 5100 5100 5100 5100 51
1000 11 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		Z. tee	L Phys	130-	135 (190	+1) 132 132 132 132 132 132 132 132 132 132
100000		Z. tec	L Phys	130-	135 (19)	
000000 100000 10000 1000 1000 1000 100		Z. fee	L Phys	130-	135 (19)	41) 8109 8100 8100 8100 8100 8100 8100 8100 8100 8100 8100 8100 8
0000000 11/25 4 4 5 5 5 7 9 9 0		Z. tee	L Phys	130-	135 (19)	+1) (1+1)(1+1)
20000000000000000000000000000000000000		Z. tec	L Phys	130-	135 (19)	+1) (++) (+) (
20 20 22 20 22 20 22 20 22 20 22 22 20 22 22		Z. fee	L Phys	130-	135 (19)	+1) (14) (1
20000000000000000000000000000000000000		Z. fee	L Phys	130-	135 (19)	41) 100 100 100 100 100 100 100 1

Table 4

Ψs	z	z ²	uo	u _o ²	(I ₀ /I _m) ^{1/2}	Io/Im
. 02 . 025 . 03 . 04 . 05 . 06 . 07 . 08 . 09	. 1078 . 1201 . 1312 . 1507 . 1676 . 1828 . 1967 . 2095 . 2214	.01162 .01442 .01721 .02271 .02809 .03342 .03869 .04389 .04389 .04902	1.0100 1.0126 1.0151 1.0202 1.0253 1.0304 1.0356 1.0408 1.0460	1.0202 1.0253 1.0305 1.0408 1.0513 1.0618 1.0725 1.0833 1.0942	. 1089 . 1216 . 1332 . 1538 . 1718 . 1884 . 2037 . 2181 . 2316	.01185 .01478 .01773 .02364 .02953 .03549 .04150 .04755 .05364
.10 .15 .2 .25 .3 .35	.2326 .2807 .3199 .3535 .3833 .4095	.05410 .07879 .1023 .1250 .1469 .1677	1.0513 1.0779 1.1052 1.1331 1.1619 1.1913	1.1052 1.1618 1.2214 1.2840 1.3499 1.4191	. 2445 . 3026 . 3534 . 4006 . 4453 . 4879	.05979 .09154 .1249 .1605 .1983 .2380
.4 .5 .55 .6 .7 .8 .9 1.0	. 4338 . 4561 . 4765 . 4957 . 5137 . 5466 . 5753 . 6024 . 6262	. 1882 . 2080 . 2270 . 2457 . 2639 . 2988 . 3310 . 3629 . 3921	1.2214 1.2523 1.2840 1.3165 1.3499 1.419 1.492 1.568 1.649	1.4918 1.5683 1.6487 1.7333 1.8221 2.014 2.226 2.460 2.718	.5299 .5711 .6118 .6526 .6935 .7758 .8584 .9448 1.032	. 2808 . 3262 . 3743 . 4259 . 41.09 . 6018 . 7368 . 8927 1. 066
1.1 1.2 1.3 1.4 1.5 1.6 1.7 1.8 1.9	.6484 .6689 .6877 .7049 .7209 .7364 .7508 .7508 .7641 .7763	. 4204 . 4474 . 4729 . 4969 . 5197 . 5423 . 5637 . 5838 . 6026	1.733 1.822 1.915 2.014 2.117 2.226 2.340 2.460 2.586	3.004 3.320 3.669 4.055 4.482 4.953 5.474 6.050 6.686	1.124 1.219 1.317 1.420 1.526 1.639 1.757 1.879 2.007	1.263 1.485 1.735 2.015 2.329 2.686 3.086 3.532 4.029
2.0 2.1 2.2 2.3 2.4 2.5 2.6 2.7 2.8 2.9	.7879 .7996 .8095 .8195 .8289 .8378 .8455 .8455 .8533 .8610 .8682	. 6208 . 6394 . 6553 . 6716 . 6871 . 7019 . 7149 . 7281 . 7413 . 7538	2.718 2.858 3.004 3.158 3.320 3.490 3.669 3.857 4.055 4.263	7.389 8.166 9.025 9.974 11.023 12.18 13.46 14.88 16.44 18.17	2.142 2.285 2.432 2.588 2.752 2.924 3.102 3.292 3.491 3.701	4.587 5.221 5.914 6.699 7.574 8.549 9.623 10.834 12.19 13.20

Emitter Region Potential and Its Relation to Emitter Properties and Current Flow. (See Sections 43 and 44 and Fig. 9.)

Calculation of 338 radiation power using Hottel formula - grey Durfor $P = A\sigma(T, 4 - T_2) - \frac{1}{2}$ $\frac{1}{\varepsilon_1} + \frac{1}{\varepsilon_2} - 1$ T, = 1538 K T, 4 = (1.54) × 1012 = 5.6 × 1012 = 968 $=(.81)^{4} \times 10^{12} = .43$ T2 = 810°K T12 = V810×1538 = 1120 E12=.127. 8, = ,2 $\frac{1}{\epsilon_{1}} = 5$ $\frac{1}{\epsilon_{12}} = 7.9$ $\frac{1}{\epsilon_{12}} = 7.9$ $\frac{1}{\epsilon_{12}} = 7.9$ $\frac{1}{11.9} = .084$ $(T, 4 - T_2^4) = 5,2 \times 10^{12} \times .084 = .437 \times 10^{12}$ 0 = 5.65 × 10-8 P = 2,47 × 10 + wath/m2 = 2.47 Watts/cm2 $\frac{I_{max}}{I_{m}} = \frac{2.02}{.464} = 4.35$ $\phi_{e} = 2.7$, 1325 ln 4,35 = , 195 $\phi_R = 2.5$ Electron cooling = $2.02 \times 2.5 \times 10^4 = 5 \times 10^4$ Effat Power max = $\frac{.84}{7.47} = 11.2\%$

Table 3E (Emitter Space) (Continued)

Numerical Solution¹ to the Langmuir Equation for Space Charge in the Emitter Space (Eq. 36-1).

Ψs	Xs	x _s /x _m	$(\chi_{\rm s}/\chi_{\rm m})^2$
8.0	1.788	. 9900	.9802
9.0	1.795	. 9939	.9878
10.0	1.799	. 9961	.9921
12.0	1.803	. 9983	.9967
14.0	1.805	. 9994	.9989
16.0	1.805	. 9994	.9989

Based on tables computed by P. H. J. A. Kleynen, Philips Res. Rep. 1, 81 (1946).

Note 1. See Eqs. 37-1; 37-3; 37-5 and 37-6 for empirical equations for these data and the means for extrapolation.

Note 2. The limiting value of χ_s is $\chi_m = 1.806$.

Note 3. Definitions: $\psi_s = V_s / V_T = qV_s / kT$ and $\chi_s^2 = (x_s / x_1)^2$ with $(x_1)^2$ given by Eq. 35-2.

\$, should be (2.5-,133) = 2.37 ev Since Pis shown to be 1.91 at is to be expected that \$, \$1.91 and condition above is satisfied H&K stow max eff at V=.623V See table I at $\Sigma = 2.31$ = 3.692.31 × .1325 = ,306 which is change in voltage from 2.7 .: V=(2.39-1.91)= .48 Current is 3.69×,465= 1,71 ×10 × 10 × 10 m2 Power is (+8 * x 1,7 * x 104) = \$\$\$ 0,82 × 10 Compared with 0.84x10 \$ = 2,39 and el. cooling is 4.08 x 10 4 m/m 2 $e/f = \frac{.82}{2.47 + 4.08}$ = 12,5%

Table 3E (Emitter Space) (Continued)

Numerical Solution¹ to the Langmuir Equation for Space Charge in the Emitter Space (Eq. 36-1).

Ψs	Xs	x_s/x_m	$(x_s/x_m)^2$
1.1	1.171	. 6484	. 4203
1.15	1.189	. 6584	. 4335
1.2	1.208	. 6689	. 4473
1.25	1.225	. 6783	. 4602
1.3	1.242	. 6877	. 4731
1.35	1.258	. 6966	. 4853
1.4	1.273	.7049	.4970
1.45	1.288	.7132	.5086
1.5	1.302	.7209	.5197
1.6	1.330	.7364	.5424
1.7	1.356	.7508	.5638
1.8	1.380	.7641	. 5837
1.9	1.402	.7763	. 6028
2.0	1.423	.7879	. 6208
2.1	1.444	.7996	. 6392
2.2	1.462	.8095	. 6552
2.3	1.480	. 8195	.6714
2.4	1.497	. 8289	.6871
2.5	1.513	. 8378	.7018
2.6	1.527	. 8455	.7150
2.7	1.541	. 8533	.7282
2.8	1.555	. 8610	.7413
2.9	1.568	. 8682	.7539
3.0	1.580	.8749	.7652
3.1	1.590	.8804	.7751
3.2	1.602	.8870	.7867
3.3	1.611	.8920	.7956
3.4	1.621	.8976	.8057
3.5	1.631	.9031	.8155
3.6	1.639	.9075	.8235
3.8	1.655	.9164	.8398
4.0	1.670	. 9247	. 8551
4.2	1.683	. 9319	. 8683
4.4	1.694	. 9380	. 8799
4.6	1.705	. 9441	. 8913
4.8	1.715	. 9496	. 9017
5.0	1.724	. 9546	. 9112
5.5	1.742	. 9646	.9305
6.0	1.756	. 9723	.9455
6.5	1.767	. 9784	.9572
7.0	1.776	. 9834	.9570
7.5	1.783	. 9873	.9746

V V/VT J Io 1.815 .241 ,204 2.79 3,78 ,502 .111 1.52 1540 4.07 .099 1.36 ,570 4.30 ,089 1.22 ,081 595 4.49 1.11 ,618 4.66 .075 1.03 4.81 ,638 ,96 ,070 5.05 ,061 ,670 ,836 5.29 .701 , 699 ,0J1 5.52 ,046 1732 ,630 ,438 6,04 ,800 ,032 ,274 .885 6.66 ,020 ,164 .945 7.12 1012 ,118 7.54 ,0086 1.00 7.92 ,070 .0051 1.05 9.05 ,027 12 10020 area (.125×2.54)²TT = .0790m² used area of ,073

Recalculation T= 154000 $V_{T} = 0.1325$ $V_{T}^{2} = 0.364$ V-3/2 = 48x10-3 $I_{m(obs)} = 0.42 \times 10^{\circ} a/m^{2} \qquad V_{F} = 6.2$ $V_{F} = .82$ $W^{2} = \frac{9.66 \times 70^{-6} \times 48 \times 70^{-3}}{.42 \times 70^{4}} = 1.105 \times 10^{-10}$ $W = 1.05 \times 10^{5} M$ $-1_{max} = 0.42 \times 10^{4} [1+0.31 \times 11.4]$ = 1.90×104 4.53 $P_{max} = 3.7 \times 10^{-6} \times .364 \times \frac{(.82)^2}{1.10 \times 10^{-10}}$ = 0.82 × 10 4 n/m2 $V_{out} = \frac{.82}{..9} = 0.42$ = <u>.383 × 6.2 × .82</u> = .43 4.53

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

 $N_0 = 3 \times 10^{21}$

		$\mathbf{E}=6$	E =8	E =9	E = -1.0) $E = -1.1$	E = -1.2	E = -1.4	E = -1.6
v_{T}^{-1}	μ'	щ	μ	μ	м	μ	H	μ	μ
8 10 12 14 16 18 20 22 24 26	1.511 1.175 .957 .804 .691 .604 .536 .480 .435 .397	-1.425 -1.107 901 761 666 603 560 529 505 486	-1.425 -1.110 917 802 733 686 652 625 603 585	-1.426 -1.117 939 840 778 734 701 675 653 635	-1.428 -1.130 972 883 826 783 751 725 703 685	-1.433 -1.152 -1.012 930 874 833 801 775 753 735	-1.441 -1.184 -1.056 979 924 883 851 825 803 785	-1.478 -1.265 -1.152 -1.077 -1.024 983 951 925 903 885	-1.543 -1.357 -1.250 -1.177 -1.124 -1.083 -1.051 -1.025 -1.003 985
		E =6	E =8	E =9	E = -1.0	E = -1.1	E = -1.2	E = -1.4	E = - 1.6
v_{T}^{-1}	$\frac{d\mu'}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_{T}}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dv_T}$	$\frac{d\mu}{dV}_{T}$	$\frac{d\mu}{dV_{\rm T}}$
8 10 12 14 16 18 20 22 24 24 26	13.589 13.254 12.981 12.750 12.550 12.373 12.215 12.072 11.941 11.821	-12.889 -12.521 -12.092 -11.298 - 9.877 - 8.316 - 7.180 - 6.479 - 6.061 - 5.806	-12.850 -12.215 -10.682 - 8.546 - 7.117 - 6.389 - 6.006 - 5.800 - 5.674 - 5.587	-12.785 -11.693 - 9.360 - 7.455 - 6.520 - 6.082 - 5.860 - 5.730 - 5.641 - 5.571	-12.638 -10.776 - 8.190 - 6.807 - 6.218 - 5.947 - 5.801 - 5.704 - 5.630 - 5.566	-12.333 - 9.640 - 7.381 - 6.446 - 6.069 - 5.887 - 5.762 - 5.695 - 5.626 - 5.565	-11.784 - 8.603 - 6.877 - 6.251 - 5.996 - 5.860 - 5.768 - 5.691 - 5.625 - 5.564	-10.041 - 7.281 - 6.395 - 6.090 - 5.943 - 5.844 - 5.762 - 5.690 - 5.624 - 5.564	-8.413 -6.693 -6.228 -6.029 -5.932 -5.840 -5.761 -5.689 -5.624 -5.564

(Continued on next page) Sheet 8 S. .

 $\phi_R = .1325 (39.59 + 3.67 - 3.67)$ 43.26 23.08 20,16 .08 (11.54)2= 23.08 = 2.67 P2 = 2.67 - .82 = 1.85 \$ = 2.67 - .1325 ln 4.53 \$= 2.47 2.47 \$ +.265 .265 \$ 2.735× 1.9×104 2,735 Cooling 5,2 × 10 × W/m2 126 2.67 - , 306 = 2.364 1.85 .51 Vout Pout = .79 W Canent is 3,69× 7/2 = 1,55

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

 $N_0 = 10^{21}$ E=-1.0 E=-1.1 E=-1.2 E=-1.4 E=-1.6 E = - .8 E=-.9 E = - .6 V_T^{-1} µ1 4 H μ p. 14 12 4 H -1.562 -1.563 8 1.648 -1.562 -1.562 -1.565 -1.568 -1.587 -1.634 10 1.285 -1.216 -1.218 -1.220 -1.226 -1.238 -1.260 -1.328 -1.415 -1.033 12 1.048 - .991 - . 998 -1.010 -1.067 -1.107 -1.199-1.296 - .858 .882 - .835 - .888 - . 927 - .972 -1.019-1.216 14 -1.117- .774 16 .759 - .724 - .815 - .861 - . 909 - . 959 -1.058 -1.158- .719 . 665 - .646 - . 766 - .814 - .864 18 - .913 -1.013 -1.113 - . 594 - .729 - .778 - .878 20 . 591 - . 680 - . 828 - . 978 -1.078 22 . 530 - .557 - .650 - .700 - .750 - .800 - . 850 - .949 -1.049- .626 - . 676 - . 726 - .776 24 .481 - . 530 - . 826 - .926 -1.026 26 .439 - .508 - .606 - . 656 - .706 - .756 - .806 - .906 -1.006 E=-.8 E = - .6 E=-.9 E=-1.0 E=-1.1 E=-1.2 E= - 1.4 E = - 1.6 $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu'}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ V_{T}^{-1} -12.232 8 14.688 -13.992 -13.979 -13.956 -13.903 -13.777 -13.518 -10.220 -12.766 -11.797 -10.563 - 8.542 - 7.543 10 14.353 -13.646 -13.534-13.30412 14.080 -13.318-12.605 -11.485 -10.033 - 8.794 - 7.955 - 7.128 - 6.840 - 6.686 - 6.608 - 7.918 - 7.302 - 6.965 14 13.848 -12.849-10.546 - 9.011 - 6.505 16 13.648 -11.887 - 8.498 - 7.498 - 6.979 - 6.722 - 6.596 - 6.484 - 6.576 - 6.471 - 6.425 - 6.396 - 6.390 - 7.324 - 6.809 18 13,471 -10.285 - 6.379 - 6.338 - 6.321 - 6.312 - 6.311 20 13.313 - 8.696 - 6.735 - 6.482 22 - 7.596 - 6.431 - 6.309 - 6.264 - 6.248 - 6.242 - 6.239 - 6.239 13.171 24 13.040 - 6.928 - 6.260 - 6.202 - 6.183 - 6.176 - 6.174 - 6.174 - 6.173 - 6.531 - 6.153 - 6.113 - 6.113 - 6.125 - 6.117 - 6.114 - 6.114 26 12.920

(Continued on next page)

Sheet 7

= 2.67 .173 2.50 Cooling. 2.5 .30.6 2.806 × 1.55 = 4.35 2.47 4.35 6,82 . 79 = 11.6% at max / 2.47 5.2 ,82 7.67 10,7% 7.67

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

$N = 10^{20}$		20	nor concent.	anon and Di	ter gy Dever.	(Dection of	•)		
0		E =6	E =8	E =9	E = -1.0	E = -1.1	$\mathbf{E}=-1,\mathbf{Z}$	E = -1.4	E ≈ - 1.6
v_{T}^{-1}	μ^{i}	. н	μ	μ	μ	μ	łr.	μ	ir.
8 10 12 14 16 18 20 22 24 24 26	1.936 1.516 1.240 1.046 .903 .793 .706 .635 .577 .528	-1.850 -1.446 -1.182 997 861 758 680 624 585 556	-1.850 -1.446 -1.183 -1.001 876 795 742 704 675 651	-1.850 -1.447 -1.185 -1.011 902 835 788 753 724 701	-1.850 -1.447 -1.190 -1.032 940 880 836 802 774 751	-1.850 -1.449 -1.204 -1.066 985 928 886 852 824 801	-1.850 -1.454 -1.228 -1.107 -1.032 978 936 902 874 851	-1.853 -1.482 -1.302 -1.201 -1.130 -1.077 -1.036 -1.002 974 951	-1.864 -1.546 -1.395 -1.299 -1.230 -1.177 -1.136 -1.102 -1.074 -1.051
		E =6	$\mathbf{E}=8$	E =9	E = - 1.0	E = - 1.1	E = -1.2	E = -1.4	$\mathbf{E}=-1,6$
v_{T}^{-1}	$\frac{d\mu'}{dV_{\rm T}}$	$\frac{d\mu}{dV_{T}}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV}_{T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$
8 10 12 14 16 18 20 22 24 24 26	16.990 16.656 16.382 16.151 15.951 15.774 15.616 15.473 15.342 15.222	-16.297 -15.961 -15.682 -15.424 -15.107 -14.493 -13.172 -11.282 - 9.644 - 8.574	-16.295 -15.949 -15.590 -14.837 -12.857 -10.372 - 8.794 - 7.997 - 7.600 - 7.390	-16.293 -15.923 -15.344 -13.552 -10.694 - 8.859 - 8.006 - 7.614 - 7.416 - 7.302	-16.288 -15.846 -14.645 -11.608 - 9.198 - 8.130 - 7.681 - 7.471 - 7.355 - 7.276	-16.274 -15.634 -13.253 - 9.966 - 8.399 - 7.800 - 7.549 - 7.420 - 7.335 - 7.268	-16 242 -15,118 -11,543 - 8,946 - 8,002 - 7,663 - 7,496 - 7,401 - 7,328 - 7,266	-16.243 -12.708 - 9.208 - 8.073 - 7.715 - 7.562 - 7.467 - 7.391 - 7.325 - 7.265	-15.018 -10.187 - 8.308 - 7.824 - 7.647 - 7.544 - 7.462 - 7.390 - 7.325 - 7.265

T = 1510VT = ,13 = 1.3.×10-2 $V_T^{3/2} = \pm \pm \pm 2 + 7 \times 10^{-3}$ $\omega = 10^{-5}$ $\frac{9.66 \times 47 \times 10^{-3} \times 10^{-6}}{10^{-10}} = 4.53 \times 10^{+3} a/m^2$ Im= 230 $\phi_{R}' = 1510(43.2 + 4.6 \times (-5))$.13 × 20.2 = 2,63 11600 \$304 $V_R = 2.63 - 1.57 = 1.06$ $\frac{V_R}{V_{-}} = 8.16$ $T_{\text{max}} = 6 \times 4.53 \times 10^{-2} = 27.18 \times 10^{+10}$ $\oint = 2.63 - .23 = 2.4$ Cooling power = $2.4 \times 27 \times 10^3 = 65 \times 10^3 / m^2$ $P_{max} = \frac{3.7 \times 10^{-6}}{10^{-10}} \cdot 36 \times \frac{(1.06)^2}{15} = \frac{5722 \times 10^4 w}{m^2}$ $eff = \frac{5722 \times 10^4 w}{m^2}$ 6.56 + 10.4 + 5 1,5 16.56 9.1% $\frac{15}{6.76} = \frac{15}{11.5} = 13\%$ 11,5-6,56 = 5 for radiation

CALENDAR FOR WEEK OF OCTOBER 6 - OCTOBER 10, 1958

PHYSICS

HARVARD UNIVERSITY AND MASSACHUSETTS INSTITUTE OF TECHNOLOGY

Monday, October 6 Harvard University 4:00 p.m. - Tea served in the Library of the Jefferson Laboratory. 4:45 p.m. - Large Lecture Hall, Jefferson Laboratory Physics and Applied Science Colloquium "Tce" Professor Bruce Chalmers Wednesday, October 8 Harvard University 3:45 p.m. - Applied Mechanics Colloquium Pierce Hall, Room 209 "Sloshing of Liquids in Circular Canals and Spherical Tanks" Professor Bernard Budiansky Harvard University Coffee will be served after the colloquium. Thursday, October 9 Harvard University 4:00 p.m. - Tea served in the Harvard College Observatory Library. 4:30 p.m. - Harvard Astronomical Colloquium, Harvard College Observatory Library "An Outline of a Physical Theory of Galactic Structure and Evolution" Professor K. F. Ogorodnikov Leningrad University Observatory Massachusetts Institute of Technology * 3:30 p.m. - Tea will be served in the Cafeteria of Lincoln Laboratory. 4:00 p.m. - Physics Colloquium, Cafteria of Lincoln Laboratory "Recent Developments in the Theory of Superconductivity" Professor John Bardeen University of Illinois

* NOTE

Transportation will be provided to Lincoln for the Colloquium of October 9. There will be busses at the entrance of the Main Parking Lot on Massachusetts Avenue at 3:00 p.m. Transportation will also be provided back to Harvard Square and M.I.T. from Lincoln at the end of the Colloquium.

Will those people who need transportation tell Miss Phillips, Room 6-306, Extension 877, by Monday, October 6.





See p28 acheckor Egg

 $0 = \frac{120 \times 10^4}{210} + 2 \ln W + \ln \frac{120 \times 10^4}{7.729 \times 10^2} - \frac{\varphi_e}{V_e}$

\$= V-

 $\frac{120}{7.729} = 15.56$ 17.192 ln 10 = 39.55

39.59 was used which is of

When I m = Im = Jult 2 Un W $P_{e} = .1325 \left(\frac{41.39}{3.67} + 3.67 - 22.90 \right) \times .42$. 42 × (.265+,82) 2.67 2.935 1.235 45.262 22.36 Pa= 1,24 = $eff = \frac{.82 \times .42}{(2.47 + 1.24)} = \frac{3.44}{3.71} = 9.28\%$

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

 $N_0 = 3 \times 10^{20}$ E = - .6 E = - .8 E=-.9 E=-1.0 E=-1.1 E=-1.2 E = -1.4 E = -1.6 v_{T}^{-1} μ' 4 μ 14 μ 14 14 μ 14 8 -1.712 1.799 -1.712 -1.712 -1.713 -1.713 -1.714 -1.722 -1.746 1.406 -1.336 -1.337 10 -1.338 -1.340-1.344 -1.356 -1.404 -1.482 12 1.149 -1.091 -1.093 -1.098-1.111 -1.134 -1.167 -1.252 -1.34714 .968 - .919 - .929 - .948 - .979 -1.019-1.064 -1.160 -1.26016 .835 - .794 - .824 - .901 - .858 - . 948 - . 997 -1.096 -1.196 18 .732 - .702 - .757 - .801 - . 897 - .848 - . 947 -1.147-1.047 - . 636 .651 - .712 - . 760 20 - .809 - .858 - . 908 -1.008 -1.108- . 590 22 . 585 - .678 - .727 - . 777 - .827 - . 877 - .977 -1.077 . 531 - .557 24 - .652 - .701 - .751 - .801 - .851 - .951 -1.051 26 . 486 - . 532 - .630 - . 680 - .729 - .779 - .829 - .929 -1.029E = - .6 E = - .8 E=-.9 E=-1.0 E = - 1.1 E = - 1.2 E = -1.4 E = -1.6 $\frac{d\mu'}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_{\rm T}}$ V_T^{-1} $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ du dVT 8 15.892 -15.198 -15.194 -15,187 -15.170 -15,131 -15.039 -12.729 -14.431 10 15.557 -14.860 -14.825 -14.748 -14,536 -14.025-13.052 -10.438 - 8.726 12 15.284 -14.569 -14.309 -13.718 -12.485 - 7.563 -10.897 - 9.551 - 8.087 -12.946 14 15.052 -14.260 -11.209 - 9.567 - 8.494 - 7.886 - 7.378 - 7.235 16 14.852 -13.745 -10.550 - 8.916 - 7.993 - 7.525 - 7.295 - 7.129 - 7.184 - 7.057 18 14.675 -12.638 - 8.678 - 7.756 - 7.332 - 7.141 - 7.004 - 6.993 20 14.517 - 7.686 -10.892 - 7.227 - 7.039 - 6.963 - 6.932 - 6.915 - 6.913 22 14.374 - 9.252 - 7.192 - 6.970 - 6.888 - 6.858 - 6.847 - 6.842 - 6.841 24 14.244 - 8.143 - 6.934 - 6.828 - 6.793 - 6.781 - 6.777 - 6.776 - 6.775 26 14.124 - 7.475 - 6.787 - 6.737 - 6.722 - 6.717 - 6.716 - 6.715 - 6.715

> (Continued on next page) Sheet 6

Take $()^2 = 2.86$ 2 = 1.65 AV = 1.65x.1325= .2185 Vout = .82 - .22 = .6015 I = 2.86×,42 = 1,2 a/cm 2 Pout = . 721 w/cm 2 \$ = 2,67 - two 1325 lu 2,86 1.05 ,139 $2,531 = \phi'$ $\frac{265}{2,796}$ Po = 2,796 × 1,2 = 3,35 2.47 eft 1721 582 12,4 0/ 1)2= 3,69 Z = 2,31 AV=,306 Vout = .82 - . 306 = .514 I = 1,55 a/cm2 Port = . 797 \$= 2,67 - ,1325 × 1,305 eft =11.8% $\frac{2.497}{.265} P_0 = 4.29$ $\frac{1}{2.47}$ 6.76

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

 $N_0 = 10^{20}$

E = - 1.4 E = -1.6E=-.8 E = -.9E=-1.0 E=-1.1 E = -1.2E= - .6 V_T⁻¹ μ' μ . 11 11 4 μ. 14 11 12 -1.850-1.850 -1.850 -1.850 -1.850 -1.853-1.864 8 1.936 -1.850 -1.447 10 1.516 -1.446 -1.446 -1.447 -1.449 -1.454 -1.482 -1.546 12 1.240 -1.182 -1.183-1.185 -1.190 -1.204 -1.228 -1.302 -1.395 -1.001 -1.032 -1.299 14 1.046 - . 997 -1.011 -1.066 -1.107 -1.201 - .876 - .940 - . 985 -1.032 -1.130 -1.230 .903 - .861 - .902 16 - .758 - .795 - . 880 - . 928 - . 978 -1.177 18 .793 - .835 -1.077. 706 - . 680 - .742 - . 788 - .836 - .886 - . 936 -1.036 -1.136 20 - . 753 22 .635 - . 624 - .704 - .802 - .852 - . 902 -1.002 -1.102 .577 - .675 - .724 - .774 - . 824 - .874 24 - .585 - .974 -1.07426 . 528 - .556 - .651 - .701 - .751 - .801 - .851 - .951 -1.051 E = -.6E = - .8 E = - .9 E = - 1.0 E = - 1.1 E = -1.2E = - 1.4 E = -1.6 $\frac{d\mu'}{dV_T}$ $\frac{d\mu}{dV_T}$ $\frac{d\mu}{dV_T}$ du V_{T}^{-1} dµ du du du dVT dVT dVT dV T TVP 16.990 -16.297 -16.295 -16.293 -16.288 -16.274 -16 242 -16.243 -15.018 8 -15.846-15.634 -15.118 -12.708 -10.187 10 16.656 -15.961 -15.949 -15.92312 16.382 -15.682 -15.590 -15.344 -14.645 -13.253 -11.543 - 9.208 - 8.308 - 9.966 - 8.946 - 8.073 - 7.824 16.151 -13,552 -11.608 14 -15.424 -14.837- 7.715 - 7.647 16 15.951 -15.107 -12.857 -10.694 - 9.198 - 8.399 - 8.002 - 7.562 -14.493 - 7.663 - 7.544 15.774 -10.372- 8,859 - 8.130 - 7.800 18 - 7.549 - 7.467 - 7.462 20 15.616 -13.172 - 8.794 - 8.006 - 7.681 - 7.496 22 -11.282- 7.997 - 7.614 - 7.471 - 7.420 - 7.401 - 7.391 - 7.390 15.473 24 15.342 - 9.644 - 7.600 - 7.416 - 7.355 - 7.335 - 7.328 - 7.325 - 7.325 - 7.265 - 7.265 - 7.302 - 7.276 - 7.268 - 7.266 26 15.222 - 8.574 - 7.390

at totat U=2.41 Z=1.28 AV=,1695 ,82 17 ,65 - vout I= 1,01 P= ,656 1325 ln, 241 = .88x, 1325 = , 1162 2,67 1116 2.554 ,265 2,819 × 1,01 = 2,84 = P 2,47 5,31 ·656 = 12.35 Pout = ,7 at ,62 V I=1,13 I = 2,69 .132 lu 2.69 = .131 ,99 2667 2.54 261 2,805 × 1,13 = Pe= 3.17 2,47 5.64 ·7 J.64 = 12,4%

Table 7						-
rante (1.2.1	100	3.4		100	1.1
all to the new years of the		24		21	6-6	
	-				~	

The	Univers	al Li	miting (Curve of	Figs.	16 and	17 is :	2 Plot
	of u ²	as a	Functio	on of S'.	(See	Section	57.)	

			u _o	u _o XsR		u ² o	S'
ψ _{sR}	x _{sR}	$\psi_{\rm sR}/2$	(ψ _{sR} /2) e	Xco	ψ _{co}	e ^ψ sR	$\psi_{\rm sR} + \psi_{\rm co}$
.02	. 1947	.01	1.0101	. 1967	.0180	1.0202	.038
.04	. 2721	.02	1.0202	. 2776	.0362	1.0408	.076
.06	. 3302	.03	1.0305	. 3403	.0533	1.0618	.113
.08	. 3783	.04	1.0408	. 3937	.0703	1.0833	.150
.10	. 4201	.05	1.0513	. 4417	.0871	1.1052	.187
.15	. 5070	.075	1.0779	. 5465	.1322	1.1618	.282
.20	.5777	.10	1.1052	.6385	.1750	1.2214	.375
.25	.6385	.125	1.1332	.7235	.223	1.2840	.473
.30	.6923	.15	1.1618	.8043	.270	1.3499	.570
.40	.7835	.2	1.2214	.9570	.372	1.4918	.772
.50	.8605	.25	1.2840	1.1049	.483	1.6487	.983
.60	.9277	. 3	1.3499	1.252	.605	1.8221	1.205
.693	.985	. 347	1.414	1.393	.732	2	1.425
.80	1.039	. 4	1.4918	1.550	.883	2.226	1.683
1.00	1.131	. 5	1.6487	1.865	1.22	2.718	2.220
1.099	1.169	. 549	1.732	2.025	1.382	3	2.481
1.2	1.208	. 6	1.8221	2.201	1.627	3.320	2.827
1.386	1.267	. 693	2.000	2.534	2.068	4	3.454
1.4	1.273	. 7	2.014	2.564	2.110	4.055	3.51
1.6	1.330	. 8	2.226	2.961	2.690	4.953	4.29
1.792	1.375	. 896	2.449	3.369	3.33	6	5.12
1.8	1.380	. 9	2.460	3.395	3.37	6.050	5.17
2.0	1.423	1.0	2.718	3.868	4.19	7.389	6.19
2.079	1.439	1.040	2.828	4.071	4.55	8	6.63
2.303	1.480	1.151	3.162	4.680	5.69	10	7.99
2.4	1.497	1.2	3.320	4.970	6.28	11.023	8.68
2.773	1.550	1.386	4.000	6.200	8.92	16	11.69
2.8	1.555	1.4	4.055	6.306	9.15	16.44	11.95
2.996	1.580	1.498	4.472	7.065	10.91	20	13.91
3.2	1.602	1.6	4.953	7.935	13.09	24.53	16.29
3.6	1.639	1.8	6.050	9.916	18.40	36.60	22.00
3.689	1.645	1.844	6.325	10.40	19.77	40	23.46
4.0	1.670	2.0	7.389	12.34	25.59	54.60	29.59
4.094	1.675	2.047	7.746	12.98	27.56	60	31.6
4.4	1.694	2.2	9.025	15.288	35.0	81.45	39.4
4.605	1.704	2.303	10.000	17.04	41.0	100	45.6

(Continued on next page)

at Z = 1,65 .82 1.85 2.67 $\frac{1}{1m} = 2.86$ 1.65×,1325 = ,2185 2.67 $\frac{122}{2,45} = \phi \qquad : I = 2.86 \times .4.2 = 1,20$ $\frac{1264}{2,71} = 2V_{4}$ P= 2.67 × 1.2 = 3,2 w/cm 2 Vout = V=+4.5 V=.596 1,85 2,446 Surface of col. 4.7 × 1325=1 ,82 \$= 2,67

The Fermi Level and Its Temperature Coefficient for Selected

Donor Concentration and Energy Level. (Section 64.)

$N_0 = 10^{21}$			MOL CONCOME	and and Da	CI KY LICYCI.	(pection of	••)		
0		E =6	E =8	E =9	E = -1.0	E = -1.1	$\mathbf{E}=-1.2$	E = -1.4	$\mathbf{E} = -1.6$
v_{T}^{-1}	μ^{1}	μ	μ	μ	μ	μ	ł r	μ	μ
8 10 12 14 16 18 20 22 24 26	1.648 1.285 1.048 .882 .759 .665 .591 .530 .481 .439	-1.562 -1.216 991 835 724 646 594 557 530 508	-1.562 -1.218 998 858 774 719 680 650 626 606	-1.562 -1.220 -1.010 888 815 766 729 700 676 656	-1.563 -1.226 -1.033 927 861 814 778 750 726 706	-1.565 -1.238 -1.067 972 909 864 828 800 776 756	-1.568 -1.260 -1.107 -1.019 959 913 878 850 826 806	-1.587 -1.328 -1.199 -1.117 -1.058 -1.013 978 949 926 906	-1.634 -1.415 -1.296 -1.216 -1.158 -1.113 -1.078 -1.049 -1.026 -1.006
		E =6	E =8	E =9	E = -1.0	E = -1.1	E = -1.2	$\mathbf{E} \approx -1.4$	E = ~ 1.6
v_{T}^{-1}	$\frac{d\mu'}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_{T}}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dv}_{T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_{\rm T}}$	$\frac{d\mu}{dV_{\rm T}}$
8 10 12 14 16 18 20 22 24 24 26	14.688 14.353 14.080 13.848 13.648 13.471 13.313 13.171 13.040 12.920	-13.992 -13.646 -13.318 -12.849 -11.887 -10.285 - 8.696 - 7.596 - 6.928 - 6.531	-13.979 -13.534 -12.605 -10.546 - 8.498 - 7.324 - 6.735 - 6.431 - 6.260 - 6.153	-13.956 -13.304 -11.485 - 9.011 - 7.498 - 6.809 - 6.482 - 6.309 - 6.202 - 6.125	-13.903 -12.766 -10.033 - 7.918 - 6.979 - 6.576 - 6.379 - 6.264 - 6.183 - 6.117	-13.777 -11.797 - 8.794 - 7.302 - 6.722 - 6.471 - 6.338 - 6.248 - 6.176 - 6.114	-13.518 -10.563 - 7.955 - 6.965 - 6.596 - 6.425 - 6.321 - 6.242 - 6.174 - 6.114	-12.232 - 8.542 - 7.128 - 6.686 - 6.505 - 6.396 - 6.312 - 6.239 - 6.174 - 6.113	-10.220 - 7.543 - 6.840 - 6.608 - 6.484 - 6.390 - 6.311 - 6.239 - 6.173 - 6.113

(Continued on next page)

Sheet 7



Addendum Remarks on a Diode Configuration of a Thermo-Electron Engine

by

Wayne B. Nottingham, George N. Hatsopoulos, and Joseph Kaye Massachusetts Institute of Technology Cambridge, Massachusetts

Three contributions to the literature have been made by us. The first two^(1,2) by Hatsopoulos and Kaye presented the results of experimental studies made on very close-spaced parallel plane diodes designed for the purpose of showing in a quantitative manner the conversion of heat to electric power. The paper by Nottingham is a theoretical analysis of this problem, by means of which the design factors are quantitatively related and the physics of the design explained in fundamental terms. Superficially there seems to be a conflict between the first two papers and the third. There are two reasons for this apparent conflict. The first results from a natural misinterpretation of the text material since most of the readers including W. B. Nottingham are likely to interpret the data as though they applied to studies with a diode spacing of 0.001 inch, whereas in fact they applied to a diode of spacing 0.001 cm. The second point of disagreement is related more specifically to the interpretation of the data presented in the two papers in that the authors state: (2)"Analysis of the space-charge barrier shows that its effects could be completely eliminated for practical purposes, for a given value of the net current, and for (of nef 2) the case of plane cathode and anode, as in Fig. 1, if the separation, y, is made very small, of the order of 0100 inch." This statement leads the reader to believe that their results apply to a diode in which space charge has been "eliminated", whereas the experimental results shown in the papers indicate clearly that space charge is playing a very important role in the actual operation

of the experimental tube. It is the purpose of this letter to point out as briefly as possible that the theory presented by W. B. Nottingham⁽³⁾ is in very exact agreement with the experimental results presented in the second paper⁽²⁾. Figure 1 shows the experimental determination of current density carried across the diode as a function of the voltage difference between the emitter and the collector. The theoretical curve shown was computed directly from the universal-diode data given in Table 8 of "Thermionic Emission". The interpretation that the theory places on these data is that the critical applied potential $V_{\rm R}$ is 0.79 volt. This potential is critical because for larger values of negative voltage the current flow across the diode is not inhibited by space charge, whereas for voltages less negative than this, a space-charge minimum exists between the emitter and the collector. At this critical voltage, the potential gradient at the collector is exactly zero. Equation 1 is a theoretical equation which relates the current density that can flow under this condition to the two parameters, namely, the spacing, w, and the voltage equivalent of the temperature V_{T} .

noto

$$I_{\rm m} = 7.729 \times 10^{-12} \ \frac{T^{3/2}}{w^2} = 9.664 \times 10^{-6} \ \frac{V_{\rm T}^{3/2}}{w^2} \ i \ amp/m^2.$$
(1)

For these data, the emitter was operated at 1540° K and the corresponding voltage equivalent of temperature is 0.1325. With a spacing w = 10^{-5} m, the current density calculated is in exact agreement with the current density observed. ⁽³⁾ Under the condition that maximum power is being delivered to the external load when the current flow is given by Eq. 2

> quart,

$$I_{max} = I_{m} \left[1 + 0.31 \left(\frac{V_{R}}{V_{T}} \right)^{4/3} \right].$$
 (2)

2.

The maximum power that can be delivered is given by Eq. 3

$$P_{\text{max}} = 3.7 \times 10^{-6} V_{\text{T}}^{1/2} \left(\frac{V_{\text{R}}}{W}\right)^{2/3}$$

The output voltage of the device is given by Eq. 4

$$V_{out} = \frac{0.383 \left(\frac{V_R}{V_T}\right) V_R}{\frac{V_R}{1+0.31 \left(\frac{V_R}{V_T}\right)}}$$
(4)

Although the maximum power depends strongly on the spacing, it is of interest to note that the voltage output under the condition of maximum power is independent of the spacing.

It is of engineering interest to answer questions concerning the efficiency of this device. The test model was obviously very inefficient and the calculated efficiencies given by Hatsopoulos and Kaye^(1,2) were based on the assumption that advanced engineering design would ultimately reduce the necessary power input to a minimum. For that design the dominating losses would then be the radiation loss from the emitter to the collector and the "electron cooling" of the emitter. The electron cooling can be calculated with ghalines accuracy from the experimental data given and the theoretical treatments of W. B. Nottingham^(3,4). Hatsopoulos and Kaye used a radiant heat transfer equation developed by Hottel⁽⁵⁾ and emissivity data of Forsyth and Watson⁽⁶⁾ to compute a radiation loss of 2.47 watts per square centimeter. With an external resistance adjusted to give an output voltage of 0.48y the computed electron cooling is 4.08 watts per square certimeter and the power delivered to the load is 0.82 watts per square centimeter thus giving an optimistic figure of 12.5 per cent as the efficiency of conversion assuming that all other 3.

(3) 2012

losses can be reduced to negligible proportions. It is hoped that these addendum remarks It is hoped that these addendum remarks will clear up misunderstandings and establish the fact that there is no basic disagreement between the experimental data presented by Hatsopoulos and Kaye and the theoretical analysis by Nottingham.

Inserts

Insert A

Furthermore these data serve to give an accurate value to the true work-function to the collector. The current flow equation establishes the fact that the surface of the collector under the condition of zero field at the collector is 2.7 volts negative with respect to the Fermi level within the interior of the emitter. Since the observed applied potential for this condition was 0.79 volt, the true work-function of the collector is the difference between these numbers, namely, 1.91 volts. Further analysis shows that the results are completely independent of the work-function of the emitter if its value is less than 0.37 volte. Since in general the emitter generally work-function is less than the collector work-function, this condition may was be satisfied for the emitters used, subject, of course, to the maintenance of suitable vacuum conditions.

ace each othe

Insert B

The equation used by Nottingham⁽³⁾ to calculate the power radiated by the emitter is more conservative than that used by Hatsopoulos and Kaye in the induction for the portexty and the absorbtivity of surfaces used in the experiment. The calculated radiation using the Hottel formula depends to a large extent on the applicability of experimental results obtained with polished, pure tungsten surfaces completely free from porosity. Can be made Additional research is needed before accurate predictions concerning the ultimate efficiency of these energy converters.

4 natures

References

- 1. G. N. Hatsopoulos and J. Kaye, J. Appl. Phys. 29, 1124, July (1958).
- 2. G. N. Hatsopoulos and J. Kaye, Proc. IRE, 46, 1574, September (1958).
- 3. W. B. Nottingham, J. Appl. Phys. (1958).
- 4. W. B. Nottingham, "Thermionic Emission", Handbuch der Physik, 21, 1, (1956) Springer-Verlag, Berlin, Germany.
- 5. H. C. Hottel, Chap. 4 of "Heat Transmission" by W. H. McAdams, McGraw-Hill, 3rd edition, 1954.
- 6. W. E. Forsythe and E. M. Watson, Jour. Opt. Soc. of America, 24, 114, April (1934).


K	Et	· / am
800	074	,1730
90-0	089	1333
1000	,105	,600
1100	.121	1.01
1200	,138	1,63
1300	.156	2.54
1400	,174	3.82
1500	:192	5.54
1600	.207	7.74
1700	1222	10.58
1800	.236	14.15
1900	1248	18.45
2000	1259	23.65

W/ 2

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Donur Competization and Evering Level. (Needlog M

536.33 hat trans among seufau Separatur ly mon- dos. media MIT Res 1951 65p.

Table 11 (Continued)

The Fermi Level and Its Temperature Coefficient for Selected Donor Concentration and Energy Level. (Section 64.)

$N_{0} = 10^{21}$		DO	Donor Concentration and Energy Level.			(Section 64.)			
· · · ·		E =6	$\mathbf{E} =8$	E=9	E = -1.0	E=-1.1	$\mathbf{E}=-1.2$	E = -1.4	E = - 1.6
$v_{\rm T}^{-1}$	μ	μ	μ	hr	ũ	μ	ц	μ	μ
8 10 12 14 16 18 20 22 24 26	1.648 1.285 1.048 .882 .759 .665 .591 .530 .481 .439	-1.562 -1.216 991 835 724 646 594 557 530 508	-1.562 -1.218 998 858 774 719 680 650 626 606	-1.562 -1.220 -1.010 888 815 766 729 700 676 656	-1.563 -1.226 -1.033 927 861 814 778 750 726 706	-1.565 -1.238 -1.067 972 909 864 828 800 776 756	-1.568 -1.260 -1.107 -1.019 959 913 878 850 826 826	-1.587 -1.328 -1.199 -1.117 -1.058 -1.013 978 949 926 906	-1.634 -1.415 -1.296 -1.216 -1.158 -1.113 -1.078 -1.049 -1.026 -1.006
		E =6	E =8	$\mathbf{E}=9$	$\mathbf{E} = -1.0$	E = - 1.1	E = - 1.2	$E \simeq -1.4$	E = - 1.6
v_{T}^{-1}	$\frac{d\mu'}{dV_T}$	$\frac{d\mu}{dV_{T}}$	$\frac{d\mu}{dV_{\rm T}}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	$\frac{d\mu}{dV_T}$	du dv _T	$\frac{d\mu}{dV_{\rm T}}$	$\frac{d\mu}{dV_{\rm T}}$
8 10 12 14 16 18 20 22 24 24 26	14.688 14.353 14.080 13.848 13.648 13.471 13.313 13.171 13.040 12.920	-13.992 -13.646 -13.318 -12.849 -11.887 -10.285 - 8.696 - 7.596 - 6.928 - 6.531	-13.979 -13.534 -12.605 -10.546 - 8.498 - 7.324 - 6.735 - 6.431 - 6.260 - 6.153	-13.956 -13.304 -11.485 - 9.011 - 7.498 - 6.809 - 6.482 - 6.309 - 6.202 - 6.125	-13.903 -12.766 -10.033 - 7.918 - 6.979 - 6.576 - 6.379 - 6.264 - 6.183 - 6.117	-13.777 -11.797 - 8.794 - 7.302 - 6.722 - 6.471 - 6.338 - 6.248 - 6.176 - 6.114	-13.518 -10.563 - 7.955 - 6.965 - 6.596 - 6.425 - 6.321 - 6.242 - 6.174 - 6.114	-12.232 - 8.542 - 7.128 - 6.686 - 6.505 - 6.396 - 6.312 - 6.239 - 6.174 - 6.113	-10.220 - 7.543 - 6.840 - 6.608 - 6.484 - 6.390 - 6.311 - 6.239 - 6.173 - 6.113

(Continued on next page) Sheet 7

Hilary Mrss. -J. El. & Conter? Vol 2, 305, Jan 1957 mpedance matching ? " uppulimits of available power on the assumption that the Space dauge barrier is non-existent p, 306, Eplans influe of the find anode and cattod work find Mories equision and (3) serve To confute the issue by expressing the anode w-f. so indiantly. analysis of p 308 Takes ement density I=ATet (mynotation) Which means V = IR + Pa IR = output volts and powers res. is I'R = IVo This The and mitte diagram NPMX R is the lotal of mic vers and in the circuit - Talk about bulk us of the coating

Table 5 (Continued)

1

Ψ _c	x _c ²	$\left[\mathbf{F}(\boldsymbol{\psi}_{\mathbf{c}})\right]$	$\left[\mathbf{F}(\boldsymbol{\psi}_{c})\right]^{3/4}$	$\left[\mathbf{F}(\psi_{c})\right]^{3/2}$	
4.00	14.190	6.8708	4.2438	18.01	
4.50	16.394	7.5657	4.5618	20.81	
5.00	18.662	8.2486	4.8672	23.69	
5.50	21.004	8.9243	5.1633	26.66	
6.00	23.406	9.5926	5.4507	29.71	
6.50	25.867	10.255	5,7306	32.84	
7.00	28.388	10.911	6,0033	36.04	
7.50	30.958	11.559	6,2690	39.30	
8.00	33.594	12.205	6,5299	42.64	
9.00	39.000	13.483	7,0363	49.51	
10.0	44.622	14.749	7.5260	56.64	
11.0	50.424	16.002	8.0006	64.01	
12.0	56.400	17.241	8.4611	71.59	
13.0	62.552	18.473	8.9107	79.40	
14.0	68.857	19.696	9.3493	87.41	
15.0	75.342	20.914	9.7796	95.64	
16.0	81.957	22.115	10.198	104.0	
18.0	95.648	24.516	11.018	121.4	
20.0	109.83	26.885	11.807	139.4	
25.0	147.87	32.782	13.700	187.7	
30.0	188.79	38.587	15.482	239.7	
35.0	232.26	44.294	17.170	294.8	
40.0	278.22	49.966	18.794	353.2	
45.0	326.89	55.637	20.372	415.0	
50.0	377.52	61.236	21.891	479.2	
60.0	484.88	72.357	24.809	615.5	
70.0	600.25	83.426	27.604	762.0	
80.0	722.53	94.400	30.285	917.2	
90.0	850.89	105.26	32.863	1080.1	
100.0	985.96	116.16	35.378	1252.	
150.0	1745.6	169.97	47.074	2216.	
200.0	2626.6	223.44	57.741	3334.	
300.0	4692.3	328.57	77.175	5956.	
400.0	7103.1	433.22	94.958	9017.	
500.0	9808.9	537.20	111.58	12451.	
600.0	12783.	640.95	127.39	16227.	
700.0	16002.	744.48	142.52	20313.	
800.0	19432.	847.43	157.06	24667.	
900.0	23074. 26929.	950.20 1053.3	171.14 184.89	29290. 34184.	

Collector Region Potential and Its Relation to Emitter Properties and Current Flow. (Use with Eq. 46-2 and related equations.)

(Continued on next page)

Hilary Mrss. -J. El. + Conter? Vol 2, 305 Jan 1957 mpedance matching ? " uppulmits of available power on the assumption that the space dauge banier is non-existent P. 306, Eplanstinflune of the function and and cattod work funct Mories equisions and (3) serve To confute the issue by expressing the anode w-f. so indianity. analysison p 308 Takes ement density I=ATet (mynotation) Which means V = IR + Pa IR = output volts and powers res. is I'R = IV. This the ana mitte diagram NPMX R is the total of mic reason o in the circuit - Talk about bulk roof the coating

and the meleface layer" does not 2 priva out the point clearly all of Mosi's 1st analysis applies only if the guo field emission It cathodo is less than I mo of my equation (2) Im = 9.66 × 10 - 6 - 4.2 W2 Juite lekely than Vout = V7 hiseg(4) Talksabout a volue of 1a /cn 2 = 10 a/m at V_7 = #### 0,1 ~ (160 %) Use above and solve Afre W, $W^2 = \frac{6.66 \times 10^{-10} \times 10^{-3}}{10^{-3}}$ 1= 2 × 10-10 m2 ~ 14×10-6 M or 14 po and uses an opid contes

Ψc	xc ²	$\left[\mathbf{F}(\boldsymbol{\psi}_{\mathbf{c}})\right]$	$\left[F(\psi_{c})\right]^{3/4}$	$\left[F(\psi_{c})\right]^{3/2}$
.01	.02074	.08849	.16227	.02633
.02	.04215	.1420	.23132	.05351
.03	.06396	.1875	.28494	.08119
.04	.08602	.22846	.33045	.1092
.05	.1084	.26654	.37094	.1376
.06	.1311	.3025	.40792	. 1664
.07	.1540	.3369	.44215	. 1955
.08	.1772	.3698	.47424	. 2249
.09	.2004	.4015	.50438	. 2544
.10	.2240	.4324	.53320	. 2843
.15	.3441	.5757	.66091	.4368
.20	.4680	.7067	.77078	.5941
.25	.5951	.8295	.86914	.7554
.30	.7251	.9462	.95937	.9204
.35	.8578	1.0584	1.0436	1.089
.40	.9930	1.1672	1.1229	1.261
.45	1.130	1.2716	1.1975	1.434
.50	1.270	1.3748	1.2696	1.612
.60	1.555	1.5736	1.4050	1.974
.70	1.847	1.7649	1.5312	2.345
.80	2.146	1.9542	1.6505	2.724
.90	2.455	2.1334	1.7652	3.116
1.00	2.766	2.3101	1.8738	3.511
1.10	3.084	2.4840	1.9786	3.915
1.20	3.408	2.6550	2.0799	4.326
1.40	4.072	2.9896	2.2735	5.169
1.60	4.757	3.3163	2.4574	6.039
1.80	5.457	3.6338	2.6319	6.927
2.00	6.180	3.9482	2.8009	7.845
2.20	6.917	4.2560	2.9631	8.780
2.40	7.667	4.5583	3.1196	9.732
2.60	8.433	4.8559	3.2711	10.70
2.80	9.217	5.1538	3.4205	11.70
3.00	10.011	5.4463	3.5651	12.71
3.20	10.824	5.7367	3.7068	13.74
3.40	11.649	6.0243	3.8453	14.79
3.60	12.482	6.3072	3.9799	15.84
3.80	13.330	6.5908	4.1134	16.92

Collector Region Potential and Its Relation to Emitter Properties and Current Flow. (Use with Eq. 46-2 and related equations.)

(Continued on next page)

Table 5

The trouble with the Mars A. analysis is that he used the wrong paramites and : could not make use of the langmin space elargo lleou early. "alement : " at is now appaient that we may Statement : attain reasonable efficiency only ley employing cathodes yielding high saturated emission densities togethe with very mall cathed andle spacing." (note no mention hur fande w. P.) and nomeans of calculating what is ment lig high Sal ening ") Moss uses inappropria parameter ") Does not uses good eque to relate experimental factors to agid Cattodes not generally useful 4) Does not show independent Thep, on anode w.t.

Table 4 (Continued)

ψs	Z	z ²	uo	u ² o	$(I_0/I_m)^{1/2}$	I _o /I _m
3.0	.8749	.7654	4.482	20.09	3.922	15.38
3.1	.8804	.7751	4.712	22.20	4.148	17.21
3.2	.8870	.7868	4.953	24.53	4.393	19.30
3.3	.8920	.7957	5.207	27.11	4.644	21.57
3.4	.8976	.8057	5.474	29.96	4.913	24.14
3.5	.9031	.8156	5.755	33.12	5.197	27.01
3.6	.9075	.8236	6.050	36.60	5.490	30.14
3.8	.9164	.8398	6.686	44.70	6.127	37.54
4.0	.9247	.8551	7.389	54.60	6.833	46.69
4.2	.9319	.8684	8.166	66.69	7.610	57.91
4.4	.9380	.8798	9.025	81.45	8.465	71.66
4.6	.9441	.8913	9.974	99.48	9.416	88.67
4.8	.9496	.9017	11.023	121.51	10.47	109.6
5.0 5.5 6.5 7.5 7.5	.9546 .9646 .9723 .9784 .9834 .9834 .9873	.9113 .9304 .9454 .9573 .9671 .9748	12.18 15.64 20.09 25.79 33.12 42.52	148.4 244.7 403.4 665.1 1096.6 1808.	11.63 15.09 19.53 25.23 32.57 41.98	135 2 227.7 381.4 636.7 1060.5 1762.4
8	.9900	.9801	54.60	2981.	54.05	2921.7
9	.9939	.9878	90.02	8103.	89.47	8004.
10	.9961	.9922	148.4	22026.	147.8	21854.
12	.9983	.9966	403.4	.16275 × 106	402.7	.1622 × 106
14	.9994	.9988	1096.6	1.2026 × 106	1096.	1.201 × 106
16	.9994	.9988	2981.	8.8861 × 106	2979.	8.875 × 106

Emitter Region Potential and Its Relation to Emitter Properties and Current Flow. (See Sections 43 and 44 and Fig. 9.)

Note 1. Ψ_s and χ_s from Table 3E.

 $z = (\chi_s/\chi_m)$ from Eq. 43-7. $u_o^2 = I_o/I_R = e^{\psi_S}$ from Eq. 43-5.

 $(I_0/I_m) = z^2 e^{\psi_s}$ from Eq. 43-6.

The two is ing soft of are

Thennionic Energy Converter K.G. Hernquist M. Kanepsky F. H. Norman Rea Rev Voe xix, 244 Juni p 244 - statement 11, that high cathod w.t. is needed for eff. is wrong. 2) Meaning of overcome space stange very vague 245 Statement "When the external cricuit between ---- " is very wrong. Max output volt \$ - \$ wrong. and does not the radiation problem Justice. Reoutica back ground lacking attripates "resonance ionization idea as a ppeud to easur Th A.V. Engelt M Steenbach - Elecktrick gasentladunge - Spinger 1932 (p130) notto Pargnint Kingdor